

DACx0004 四通道 16 位、14 位、12 位 1LSB INL 缓冲电压输出数模转换器

1 特性

- 真正的 16 位性能：1 LSB 积分非线性 (INL)/微分非线性 (DNL)（最大值）
- 超低毛刺脉冲能量：1nV-s
- 宽电源电压范围：2.7V 至 5.5V
- 支持轨到轨运行的输出缓冲器
- 电流消耗：1mA/通道
- 50MHz、四线制或三线制串行外设接口 (SPI) 兼容接口
- 用于回读和菊花链连接的 SDO 引脚
- 上电复位至零量程或量程中点
- 温度范围：-40°C 至 +125°C
- 多种封装：
 - 微型 14 引脚超薄小外形尺寸无引线 (VSON) 封装
 - 14 引脚薄型小外形尺寸 (TSSOP) 封装

2 应用

- 便携式仪表
- 可编程逻辑控制器 (PLC) 模拟输出模块(4mA-20mA)
- 闭环伺服器控制
- 数据采集系统

3 说明

DAC80004/70004/60004 (DACx0004) 分别为 16 位、14 位和 12 位高精度、低功耗、电压输出、四通道数模转换器 (DAC)。DACx0004 器件通过设计可保证单调性，拥有低于 1 LSB（最大值）的出色线性度。DAC 的基准输入在内部通过专用基准缓冲器进行缓冲。

DACx0004 器件配有上电复位电路，用于确保 DAC 输出在零量程或量程中点处上电（具体取决于 POR 引脚的状态）并保持该状态直到器件中写入有效编码为止。这些器件的电流消耗非常低（1mA/通道），是便携式、电池供电类设备的理想选择。这些器件还包含一种掉电特性。该特性可将 5V 电压下的流耗降至 3 μ A（典型值）。

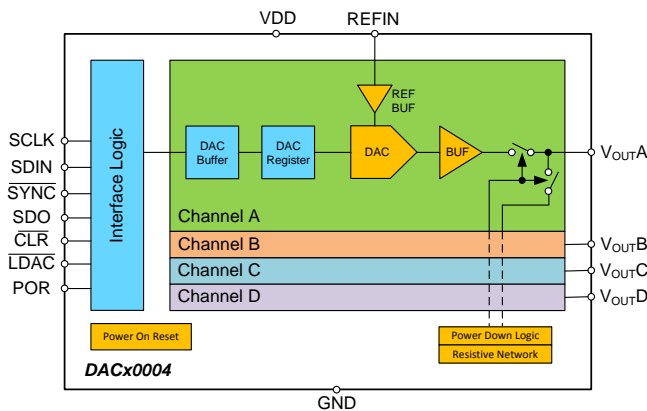
DACx0004 器件使用一个运行时钟速率高达 50MHz 的通用三线制串口。DACx0004 器件还包含一个 SDO 引脚，该引脚能够以菊花链形式连接多个器件。此接口与标准 SPI™，QSPI™、Microwire 以及数字信号处理器 (DSP) 接口兼容。DACx0004 器件采用易于装配的 14 引脚 TSSOP 封装或超小型 14 引脚 VSON 封装，在 -40°C 至 +125°C 的扩展工业级温度范围内完全额定运行。

器件信息⁽¹⁾

器件型号	封装	封装尺寸（标称值）
DACx0004	VSON (14)	3.00mm x 4.00mm
DACx0004	TSSOP (14)	5.00mm x 4.40mm

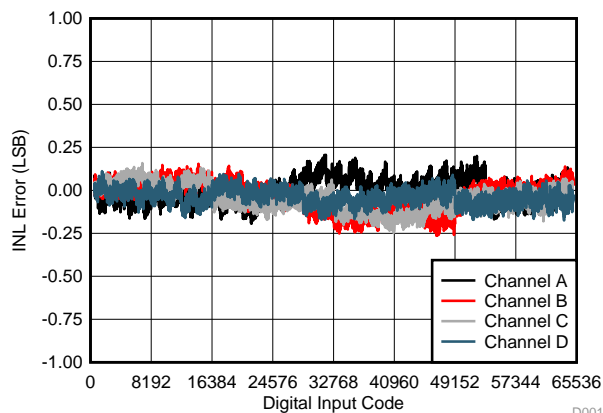
(1) 要了解所有可用封装，请见数据表末尾的可订购产品附录。

DACx0004 框图



Copyright © 2016, Texas Instruments Incorporated

线性误差与数字输入编码间的关系



D001



目录

1	特性	1	8.3	Feature Description	19
2	应用	1	8.4	Device Functional Modes	20
3	说明	1	9	Application and Implementation	26
4	修订历史记录	2	9.1	Application Information	26
5	Device Comparison Table	3	9.2	Typical Application - Digitally Controlled Asymmetric Bipolar Output	26
6	Pin Configuration and Functions	3	10	Power Supply Recommendations	28
7	Specifications	4	11	Layout	29
7.1	Absolute Maximum Ratings	4	11.1	Layout Guidelines	29
7.2	ESD Ratings	4	11.2	Layout Example	29
7.3	Recommended Operating Conditions	4	12	器件和文档支持	30
7.4	Thermal Information	4	12.1	相关链接	30
7.5	Electrical Characteristics	5	12.2	社区资源	30
7.6	DACx0004 Timing Requirements	8	12.3	商标	30
7.7	Typical Characteristics	10	12.4	静电放电警告	30
8	Detailed Description	18	12.5	Glossary	30
8.1	Overview	18	13	机械、封装和可订购信息	31
8.2	Functional Block Diagram	18			

4 修订历史记录

Changes from Original (April 2016) to Revision A

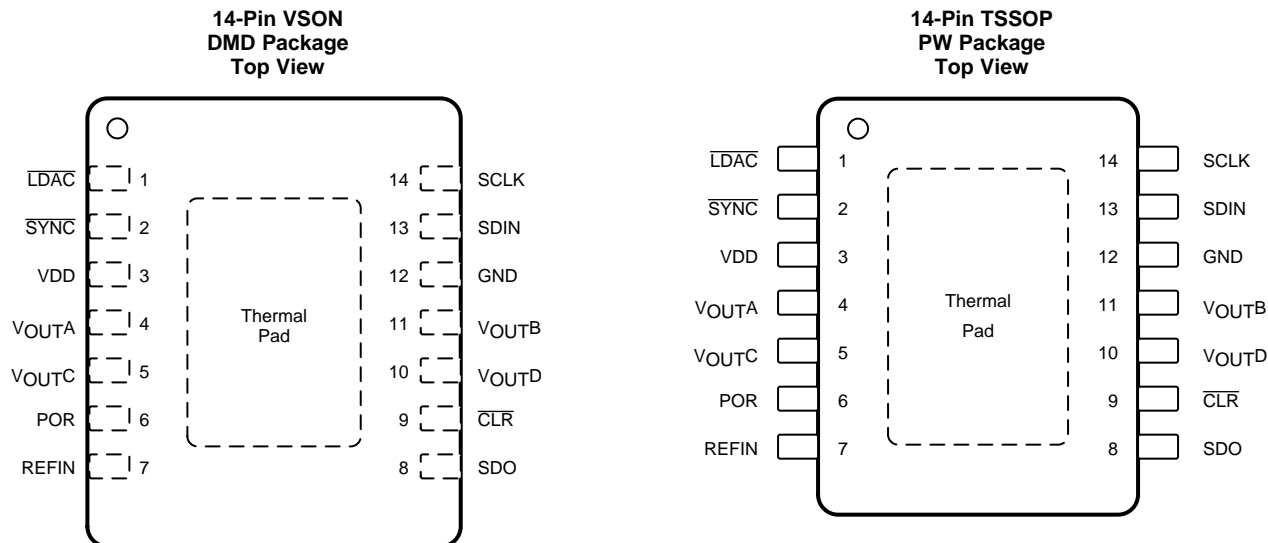
Page

• 已更改 产品预览至量产数据	1
-----------------------	----------

5 Device Comparison Table

DEVICE	RESOLUTION
DAC80004	16
DAC70004	14
DAC60004	12

6 Pin Configuration and Functions



Pin Functions

PIN		I/O	DESCRIPTION
NAME	NUMBER		
$\overline{\text{CLR}}$	9	Digital Input	Clear DAC pin, falling edge sensitive
GND	12	Power	Ground
$\overline{\text{LDAC}}$	1	Digital Input	Load DAC pin, active low
POR	6	Digital Input	Power-on-reset configuration, Connecting the POR pin to GND powers up all four DACs to zero scale. Connecting this pin to VDD powers up all four DACs to midscale.
REFIN	7	Analog Input	Voltage reference input for all channels
SCLK	14	Digital Input	Serial interface shift clock
SDIN	13	Digital Input	Serial interface digital input
SDO	8	Digital Output	Serial interface digital output for readback and daisy chaining
$\overline{\text{SYNC}}$	2	Digital Input	Serial interface synchronization, active low
VDD	3	Power	Positive power supply (2.7 V to 5.5 V)
V _{OUTA}	4	Analog Output	DAC A output
V _{OUTB}	11	Analog Output	DAC B output
V _{OUTC}	5	Analog Output	DAC C output
V _{OUTD}	10	Analog Output	DAC D output

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

	MIN	MAX	UNIT
Voltage, VDD to GND	-0.3	7	V
Voltage, digital input or output to GND	-0.3	$V_{DD} + 0.3$	V
Voltage, analog input (REFIN) or output (V_{OUTX}) to GND	-0.3	$V_{DD} + 0.3$	V
Input current to any pin except supply pins	-10	10	mA
Maximum junction temperature		150	°C
Storage temperature range, T_{stg}	-60	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$ Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±2000	V
	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	±1000	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
 (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
Voltage, VDD to GND		2.7		5.5	V
Voltage, analog input (REFIN) or output (V_{OUTX}) to GND	$2.7\text{ V} \leq V_{DD} \leq 4.5\text{ V}$	2.2		$V_{DD} - 0.2$	V
	$4.5\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	2.2		V_{DD}	V
Ambient Operating Temperature, T_A		-40		125	°C

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾		DACx0004		UNIT
		DMD (VSON)	PW (TSSOP)	
		14 PINS	14 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	39.6	99.1	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	27.3	23.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	9.0	42.8	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	0.3	0.9	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	8.9	42.0	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	6.5	N/A	°C/W

- (1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

7.5 Electrical Characteristics

All minimum/maximum specifications at $T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $2.5\text{ V} \leq \text{REFIN}^{(1)} \leq V_{DD}$, $R_{\text{load}} = 5\text{ k}\Omega$ to GND, $C_{\text{load}} = 200\text{ pF}$ to GND (unless otherwise noted), Digital inputs held at 0 V

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC PERFORMANCE⁽²⁾						
Resolution		DAC80004	16			Bits
		DAC70004	14			
		DAC60004	12			
INL	Relative accuracy ⁽³⁾				± 1	LSB
DNL	Differential nonlinearity ⁽³⁾	Ensured monotonic			± 1	LSB
TUE	Total unadjusted error ⁽³⁾	$T_A = +20^{\circ}\text{C}$ to $+40^{\circ}\text{C}$			1.5	mV
		$T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$			2	
ZCE	Zero code error	$T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, Code 0d into DAC		± 0.2	± 2	mV
		$T_A = +25^{\circ}\text{C}$, Code 0d into DAC		± 0.1		
ZCE-TC	Zero code error TC	$T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$		± 5		$\mu\text{V}/^{\circ}\text{C}$
OE	Offset error ⁽³⁾	$T_A = +20^{\circ}\text{C}$ to $+40^{\circ}\text{C}$			± 1.2	mV
		$T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$		± 0.2	± 1.8	
		$T_A = +25^{\circ}\text{C}$		± 0.2		
OE-TC	Offset error drift	$T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$		± 4		$\mu\text{V}/^{\circ}\text{C}$
FSE	Full-scale error ⁽⁴⁾	$T_A = +20^{\circ}\text{C}$ to $+40^{\circ}\text{C}$, Code 65535d into DAC			± 0.05	%FSR
		$T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, Code 65535d into DAC		± 0.01	± 0.07	%FSR
		$T_A = +25^{\circ}\text{C}$		± 0.01		
FSE-TC	Full-scale error drift ⁽⁴⁾	$T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$		± 2		ppm FSR/ $^{\circ}\text{C}$
GE	Gain error ⁽³⁾	$T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$		± 0.005	± 0.05	%FSR
		$T_A = +25^{\circ}\text{C}$		± 0.005		
GE-TC	Gain drift	$T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$		± 2		ppm FSR/ $^{\circ}\text{C}$
	Output voltage drift vs.Time	$T_A = +25^{\circ}\text{C}$, $V_{\text{out}} = \frac{3}{4}$ of full scale, 1900 hr		20		ppm FSR
	Load Regulation	$T_A = +25^{\circ}\text{C}$, $V_{\text{out}} = \text{Mid Scale}$		0.003		%
PSRR	DC Power supply rejection ratio ⁽⁴⁾	$T_A = +25^{\circ}\text{C}$, $V_{\text{out}} = \text{full scale}$		-92		dB

(1) 200 mV headroom is required between REFIN and VDD when $2.7\text{ V} \leq V_{DD} \leq 4.5\text{ V}$.

(2) Output unloaded

(3) End point fit between codes Code 512 to Code 65,024 - DAC80004, Code 128 to Code 16,256 - DAC70004, Code 32 to Code 4064 - DAC60004, Output unloaded.

(4) With 100 mV headroom between DAC output and VDD.

Electrical Characteristics (continued)

All minimum/maximum specifications at $T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $2.5\text{ V} \leq \text{REFIN}^{(1)} \leq V_{DD}$, $R_{\text{load}} = 5\text{ k}\Omega$ to GND, $C_{\text{load}} = 200\text{ pF}$ to GND (unless otherwise noted), Digital inputs held at 0 V

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
DYNAMIC PERFORMANCE						
	Output voltage settling time	$\frac{1}{4}$ to $\frac{3}{4}$ scale and $\frac{3}{4}$ to $\frac{1}{4}$ scale settling to ± 1 LSB, $R_L = 5\text{ k}\Omega$, $C_{\text{load}} = 200\text{ pF}$ to GND		5.8	8	μs
	Slew rate			1.5		$\text{V}/\mu\text{s}$
	Power-up time ⁽⁵⁾			100		μs
	Power-on glitch energy	Supply slew rate $< 5\text{ V}/\text{msec}$		8		mV
	Power-off glitch energy	DAC in power down mode (1 k Ω -GND), Supply slew rate $< 5\text{ V}/\text{msec}$		7		mV
	Output noise	0.1 Hz to 10 Hz		5		μVpp
		100 kHz BW		100		μVRMS
	Output noise density	Measured at 1 kHz		60		$\text{nV}/\sqrt{\text{Hz}}$
		Measured at 10 kHz		55		
THD	Total harmonic distortion	$\text{REFIN} = 3\text{ V} \pm 0.2\text{ V}_{\text{pp}}$, Frequency = 10 kHz, DAC at mid scale, specified by design		-80		dB
PSRR	AC power supply rejection ratio	200 mV 50 Hz and 60 Hz sine wave superimposed on power supply voltage (AC analysis)		-90		dB
	Code change glitch impulse	1 LSB change around major carry, Software LDAC mode		1		nV-s
	Channel-to-channel AC (analog) crosstalk	Full-scale swing on adjacent channel, Hardware LDAC mode		1		nV-s
	Channel-to-channel DC crosstalk	Full-scale swing on adjacent channels, Measured channel at zero scale		1		LSB
		Full-scale swing on all channel, Measured channel at zero scale		1		
	Digital crosstalk	DAC code mid scale, Adjacent input buffer change from 0000h to FFFFh or vice versa		0.2		nV-S
	Reference feedthrough	$\text{REFIN} = 3\text{ V} \pm 0.86\text{ V}_{\text{pp}}$, Frequency = 100 Hz to 100 kHz, DAC at zero scale		-85		dB
	Digital feedthrough	At SCLK = 1 MHz, DAC output static at mid scale		0.2		nV-s
OUTPUT CHARACTERISTICS						
	Voltage range		0		V_{DD}	V
	Headroom	Output loaded 5 k Ω , DAC code FFFFh		0.1		V
		Output loaded 0.5 k Ω , DAC code FFFFh		10		%FSR
RL	Resistive load		0.5			k Ω
CL	Capacitive load	$R_L = \infty$		1		nF
		$R_L = 5\text{ k}\Omega$		2		
RO	DC output impedance	Normal mode		0.5		Ω
		Power down with 100 k Ω network		100		k Ω
		Power down with 1 k Ω network		1		k Ω
	Short circuit current			36		mA

(5) Time to exit power-down mode into normal mode. Measured from 32nd falling edge SCLK to 90% of DAC final value, Characterized at mid scale.

Electrical Characteristics (continued)

All minimum/maximum specifications at $T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $2.5\text{ V} \leq \text{REFIN}^{(1)} \leq V_{DD}$, $R_{\text{load}} = 5\text{ k}\Omega$ to GND, $C_{\text{load}} = 200\text{ pF}$ to GND (unless otherwise noted), Digital inputs held at 0 V

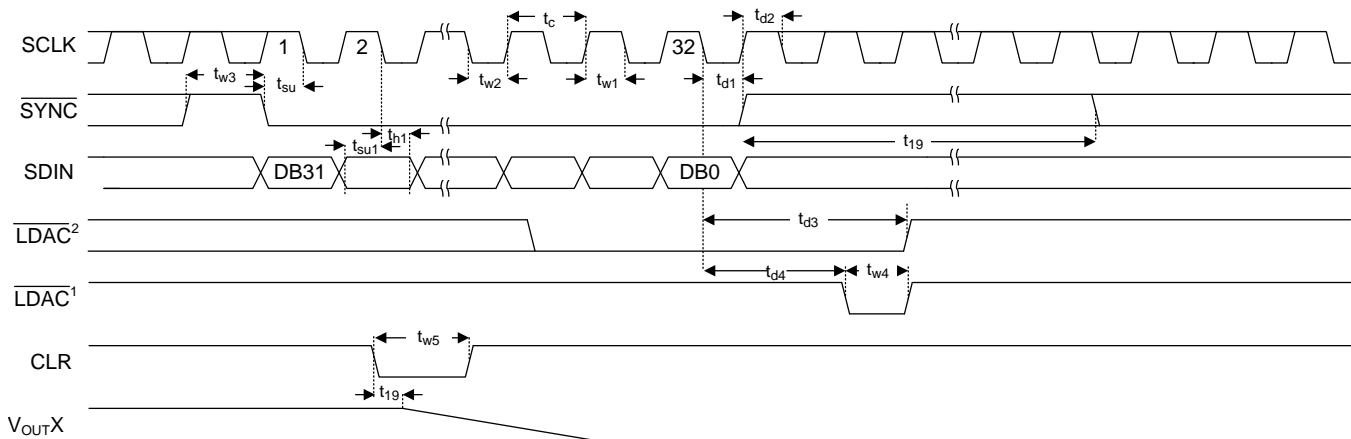
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
VOLTAGE REFERENCE INPUT						
Reference input range		$2.7\text{ V} \leq V_{DD} \leq 4.5\text{ V}$	2.2	$V_{DD} - 0.2$		V
		$4.5\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	2.2	V_{DD}		
Reference input current					450	μA
Reference input impedance				15		$\text{k}\Omega$
Reference input capacitance				10		pF
MBW	Multiplying bandwidth			340		kHz
DIGITAL INPUTS						
V_{IH}	High-level input voltage		2.3			V
V_{IL}	Low-level input voltage				0.7	V
	Input leakage	$0 < V_{\text{DIGITAL INPUT}} < V_{DD}$			± 1	μA
	Pin capacitance			4		pF
DIGITAL OUTPUTS						
V_{OH}	High-level output voltage	$I_{OH} = 2\text{ mA}$	$V_{DD} - 1$			V
V_{OL}	Low-level output voltage	$I_{OL} = 2\text{ mA}$			0.7	V
	Pin capacitance			7		pF
POWER SUPPLY REQUIREMENTS						
V_{DD}	Supply voltage		2.7		5.5	V
I_{VDD}	Supply current	$T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, Normal mode		4	5.5	mA
		$T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, Power-down mode		3	7	μA
	Power dissipation	$T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, Normal mode		20		mW
TEMPERATURE RANGE						
T_A	Specified performance		-40		125	$^{\circ}\text{C}$

7.6 DACx0004 Timing Requirements

At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$, $T_{\text{rise}} = T_{\text{fall}} = 1 \text{ nV/sec}$ (10% to 90% of V_{DD}) and timed from a voltage level of $(V_{\text{IL}} + V_{\text{IH}})/2$, SDO pin loaded with 10 pF

		4.5 V \leq $V_{\text{DD}} \leq$ 5.5 V			2.7 V \leq $V_{\text{DD}} \leq$ 4.5 V			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	
SERIAL WRITE and READ								
t_c	SCLK cycle time	20			40			ns
t_{w1}	SCLK high pulse duration	10			20			ns
t_{w2}	SCLK low pulse duration	10			20			ns
t_{su}	$\overline{\text{SYNC}}$ to SCLK falling edge setup time	15			30			ns
t_{su1}	Data setup time	5			10			ns
t_{h1}	Data hold time	5			10			ns
t_{d1}	SCLK falling edge to $\overline{\text{SYNC}}$ rising edge delay time	5			10			ns
t_{w3}	Minimum $\overline{\text{SYNC}}$ high pulse duration ⁽¹⁾	25			35			ns
t_{d2}	$\overline{\text{SYNC}}$ rising edge to SCLK fall ignore delay time	15			20			ns
t_{w4}	$\overline{\text{LDAC}}$ pulse duration low	20			30			ns
t_{d3}	SCLK falling edge to $\overline{\text{LDAC}}$ rising edge delay time	10			20			ns
t_{w5}	$\overline{\text{CLR}}$ minimum pulse duration low	10			20			ns
t_{d4}	SCLK falling edge to $\overline{\text{LDAC}}$ falling edge delay time	10			20			ns
t_v	SCLK rising edge to SDO valid time			18			18	ns
t_{d5}	SCLK falling edge to $\overline{\text{SYNC}}$ rising edge delay time	5			10			ns
t_{d6}	$\overline{\text{SYNC}}$ rising edge to SCLK rising edge delay time	5			10			ns
t_{d7}	$\overline{\text{SYNC}}$ rising edge to $\overline{\text{LDAC}}$ or $\overline{\text{CLR}}$ falling edge delay time	20			40			ns
t_{19}	$\overline{\text{CLR}}$ pulse activation time	20			20			ns
t_{20}	Successive DAC Update			2.4			2.4	μs

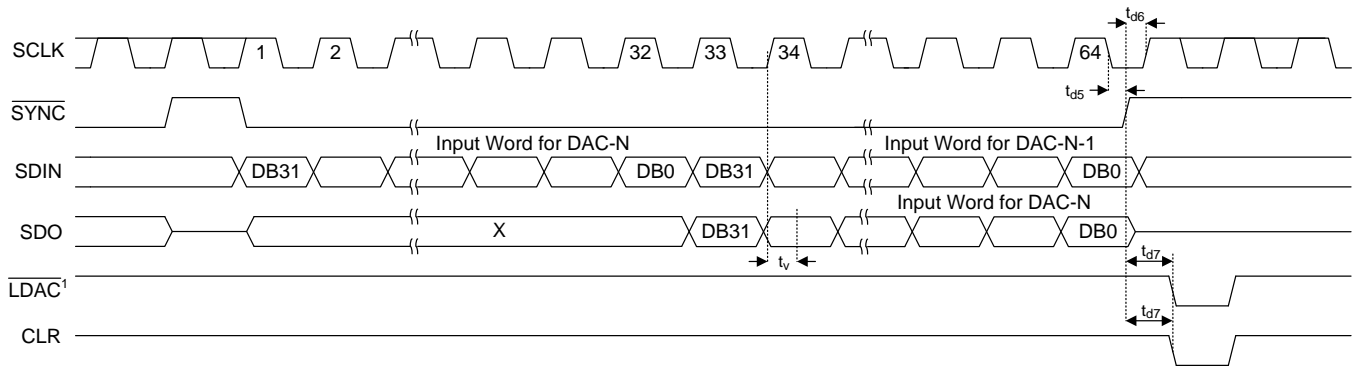
(1) Does not include output settling time



(1) Asynchronous $\overline{\text{LDAC}}$ update

(2) Synchronous $\overline{\text{LDAC}}$ update

Figure 1. Stand-Alone Timing



(1) Asynchronous \overline{LDAC} update

Figure 2. Daisy-Chain Timing

7.7 Typical Characteristics

At $T_A = 25^\circ\text{C}$, $V_{DD} = 5.5\text{ V}$, $REFIN = 5.45\text{ V}$, DAC outputs unloaded, unless otherwise noted.

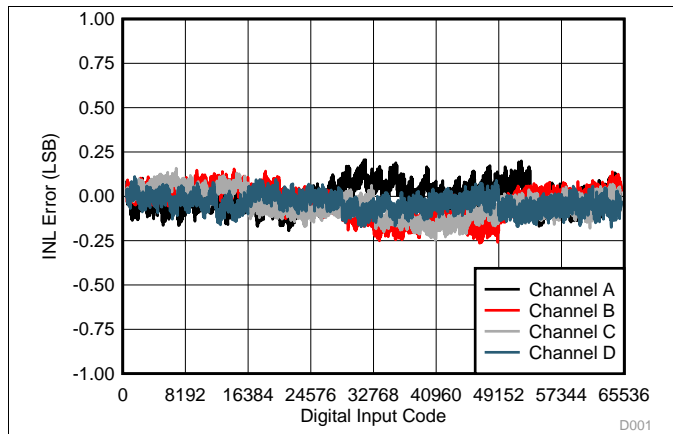


Figure 3. Linearity Error vs Digital Input Code

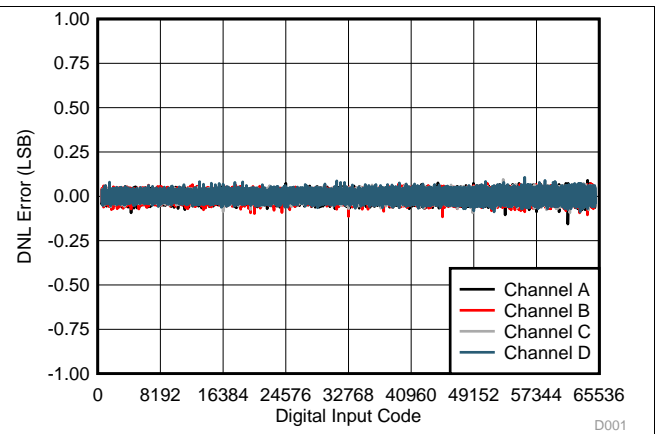
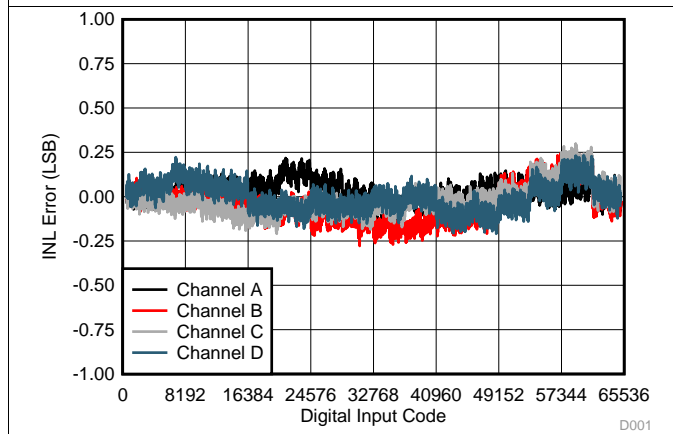
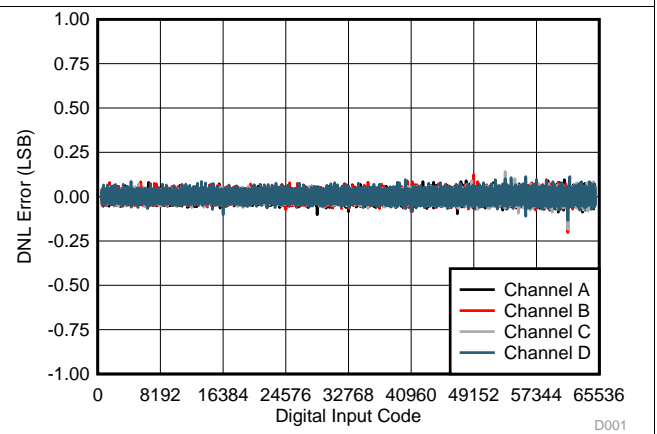


Figure 4. Differential Linearity Error vs Digital Input Code



DAC load 5 kΩ/200 pF

Figure 5. Linearity Error vs Digital Input Code



DAC load 5 kΩ/200 pF

Figure 6. Differential Linearity Error vs Digital Input Code

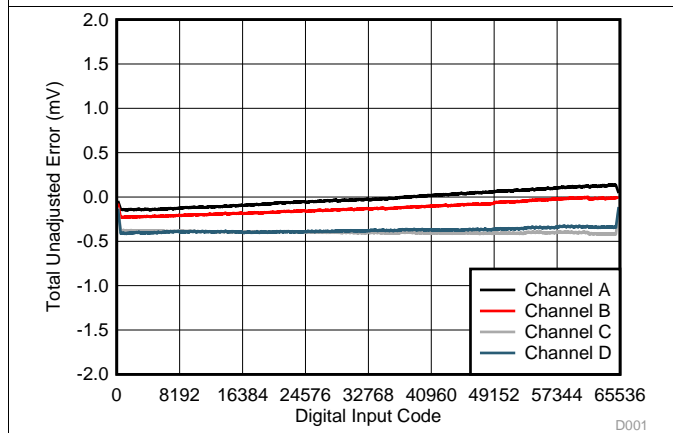
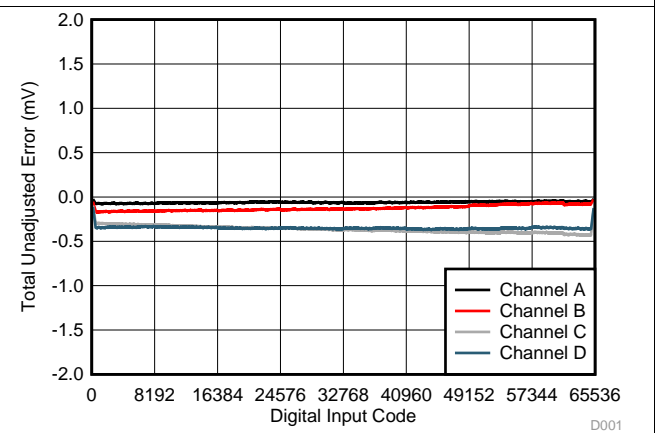


Figure 7. Total Unadjusted Error vs Digital Input Code



DAC load 5 kΩ/200 pF

Figure 8. Total Unadjusted Error vs Digital Input Code

Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, $V_{DD} = 5.5\text{ V}$, $REF_{IN} = 5.45\text{ V}$, DAC outputs unloaded, unless otherwise noted.

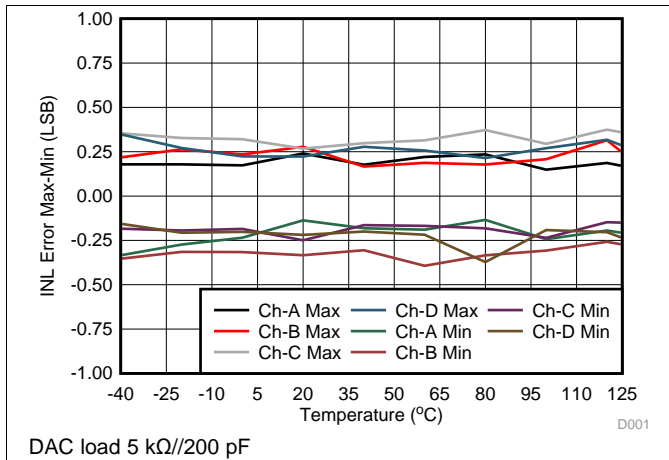


Figure 9. Linearity Error (Max-Min) vs Temperature

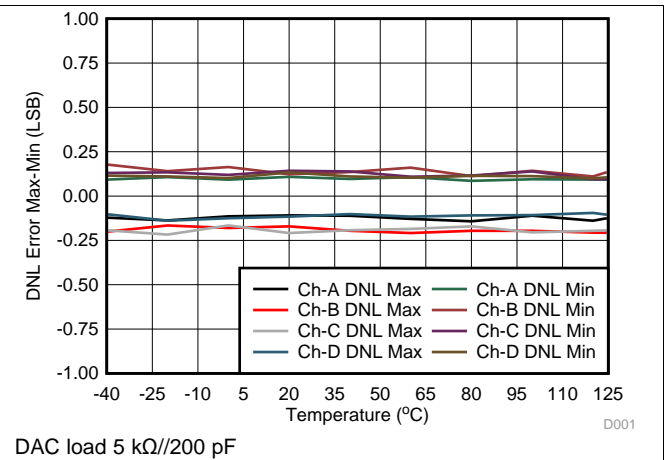


Figure 10. Differential Linearity Error (Max-Min) vs Temperature

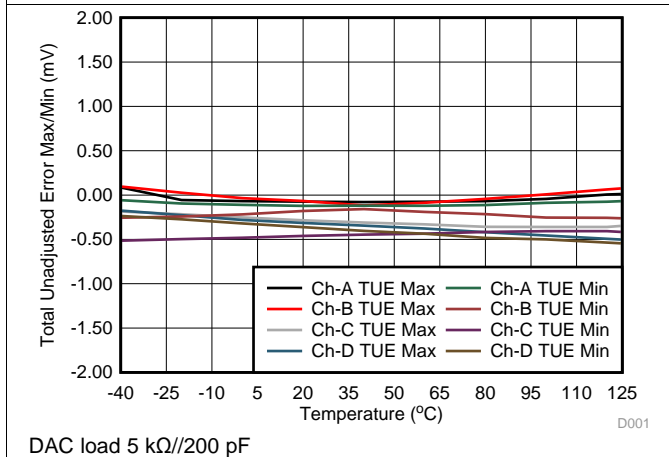


Figure 11. Total Unadjusted Error Max/Min vs Temperature

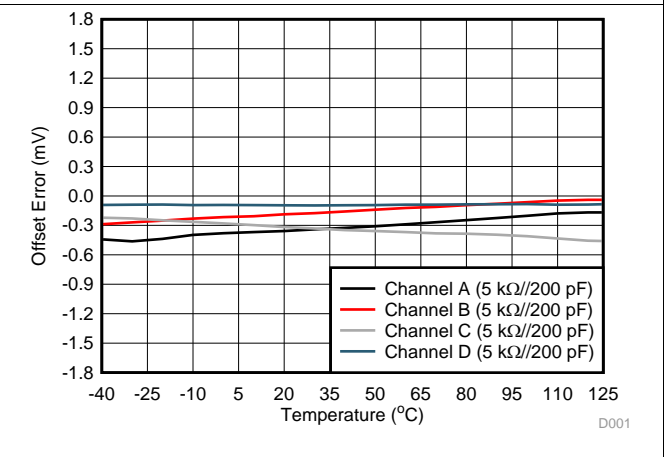


Figure 12. Offset Error vs Temperature

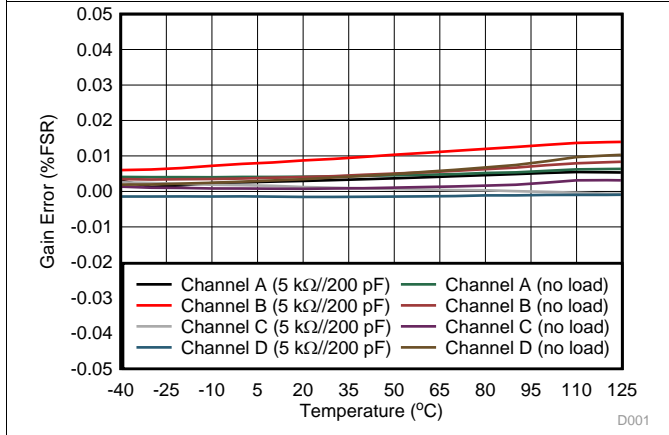


Figure 13. Gain Error vs Temperature

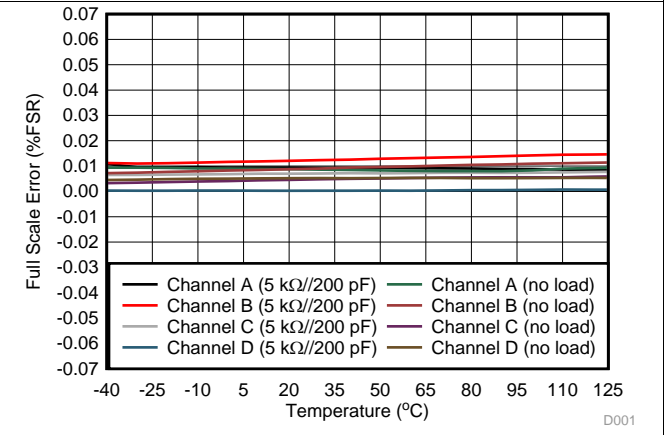


Figure 14. Full Scale Error vs Temperature

Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, $V_{DD} = 2.7\text{ V}$, $REF_{IN} = 2.5\text{ V}$, DAC outputs unloaded, unless otherwise noted.

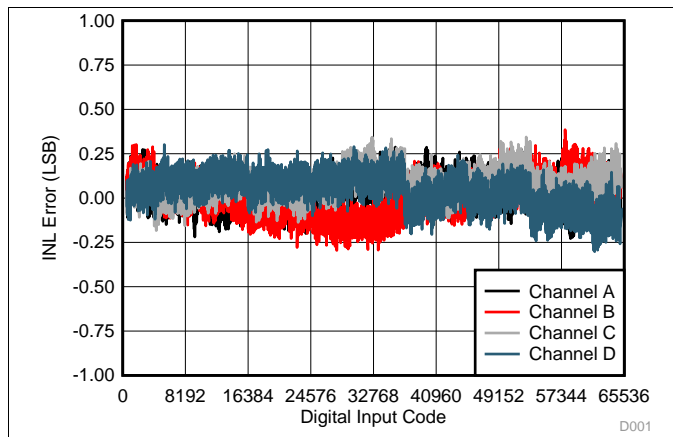


Figure 15. Linearity Error vs Digital Input Code

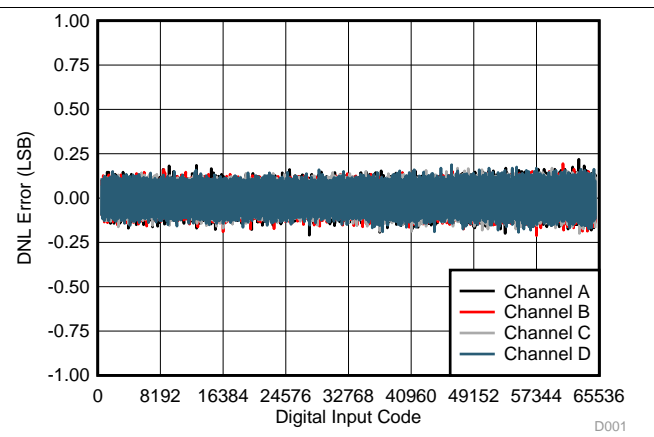
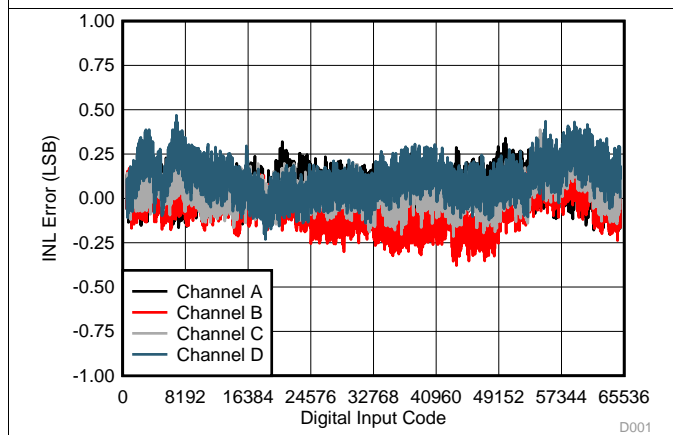
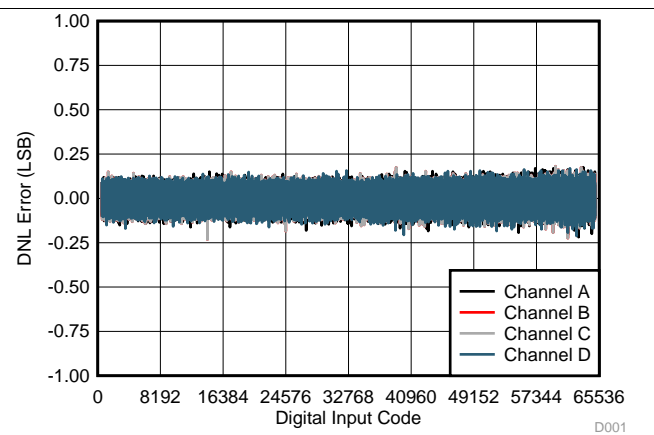


Figure 16. Differential Linearity Error vs Digital Input Code



DAC load 5 k Ω //200 pF

Figure 17. Linearity Error vs Digital Input Code



DAC load 5 k Ω //200 pF

Figure 18. Differential Linearity Error vs Digital Input Code

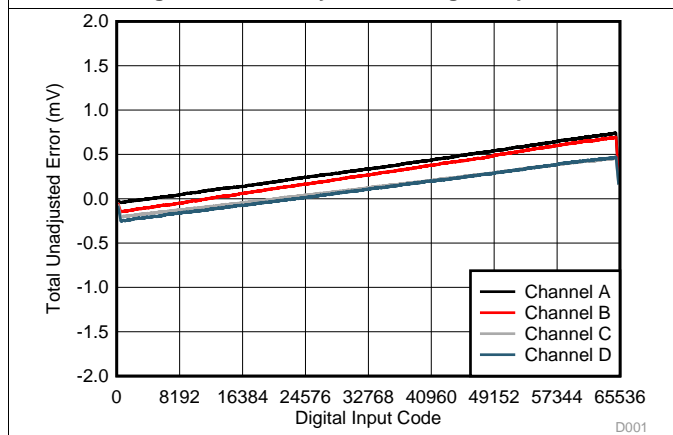
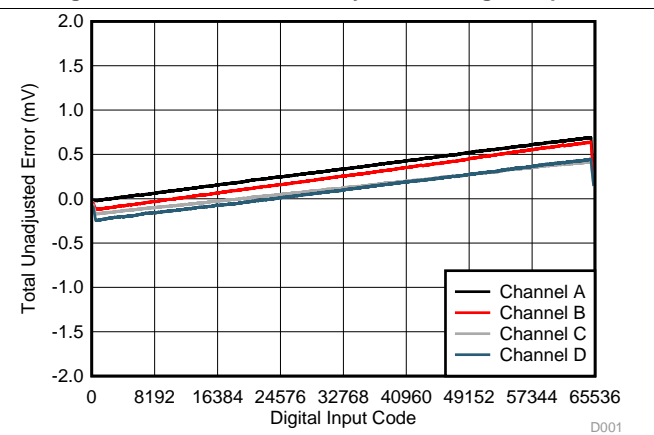


Figure 19. Total Unadjusted Error vs Digital Input Code



DAC load 5 k Ω //200 pF

Figure 20. Total Unadjusted Error vs Digital Input Code

Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, $V_{DD} = 2.7\text{ V}$, $REF_{IN} = 2.5\text{ V}$, DAC output unloaded, unless otherwise noted.

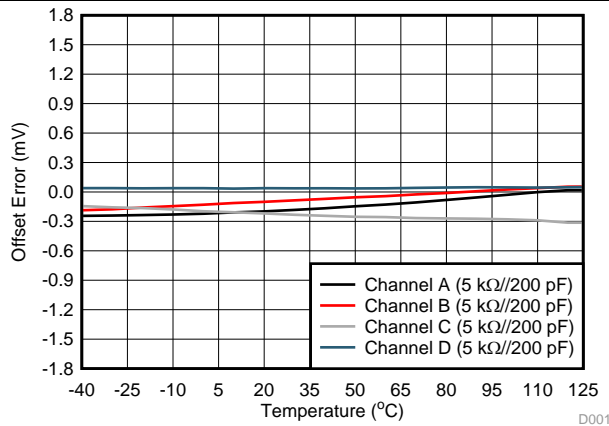


Figure 21. Offset Error vs Temperature

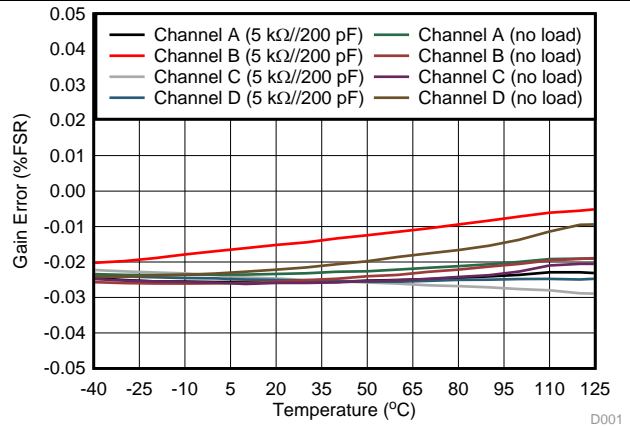


Figure 22. Gain Error vs Temperature

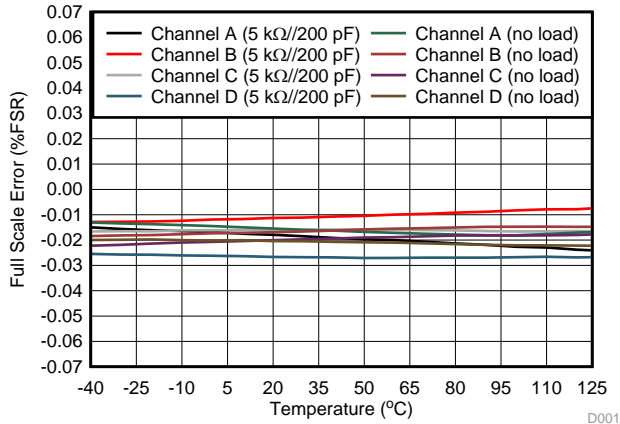
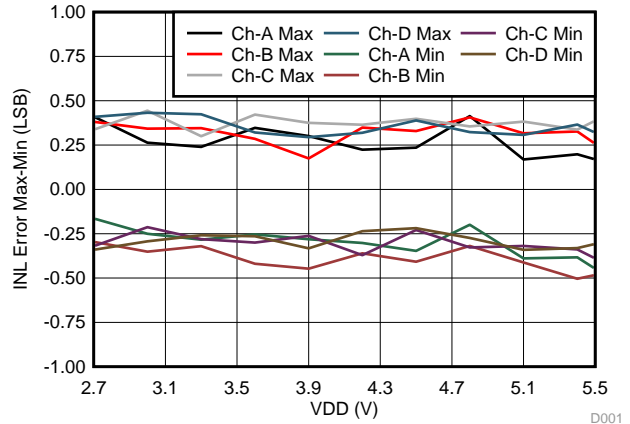
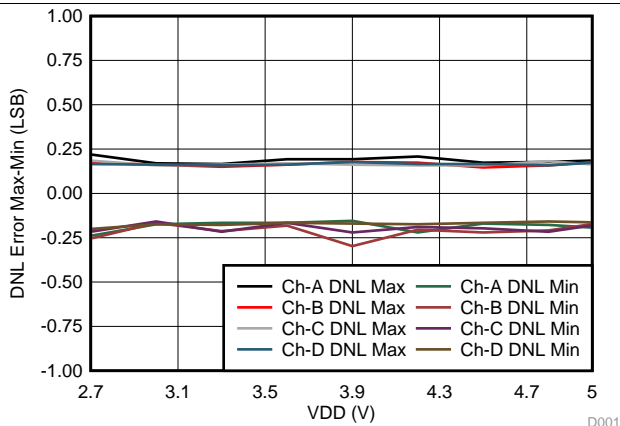


Figure 23. Full Scale Error vs Temperature



DAC load 5 kΩ/200 pF

Figure 24. Linearity Error (Max-Min) vs Power Supply Voltage



DAC load 5 kΩ/200 pF

Figure 25. Differential Linearity Error (Max-Min) vs Power Supply Voltage

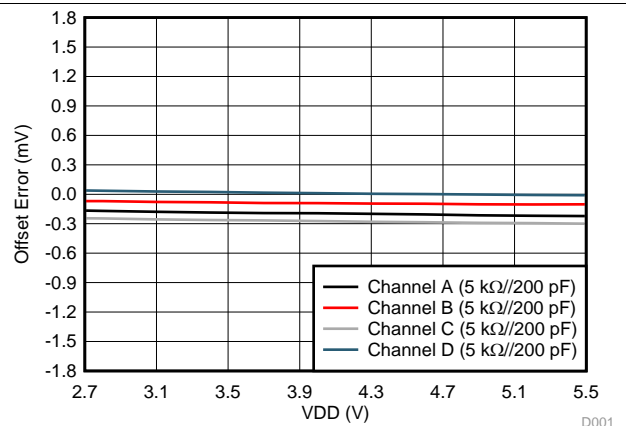


Figure 26. Offset Error vs Power Supply Voltage

Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, $V_{DD} = 5.5\text{ V}$, $REF_{IN} = 2.5\text{ V}$, DAC output load = $5\text{ k}\Omega || 200\text{ pF}$, unless otherwise noted.

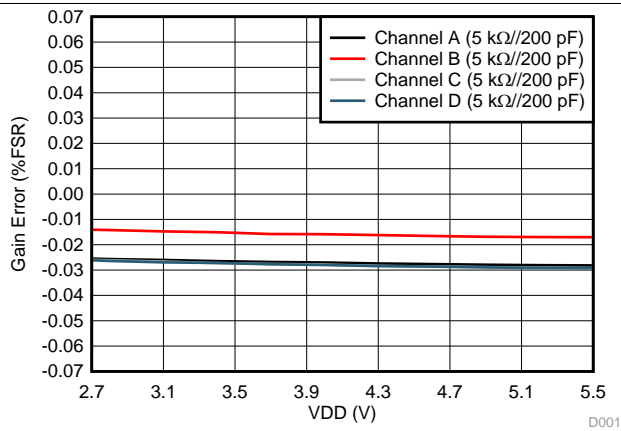


Figure 27. Gain Error vs Power Supply Voltage

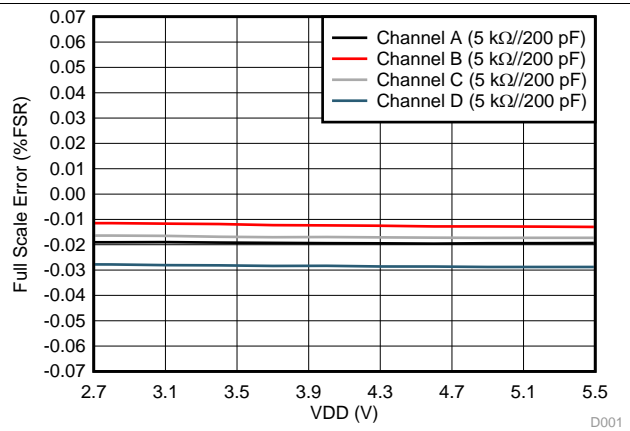


Figure 28. Full Scale Error vs Power Supply Voltage

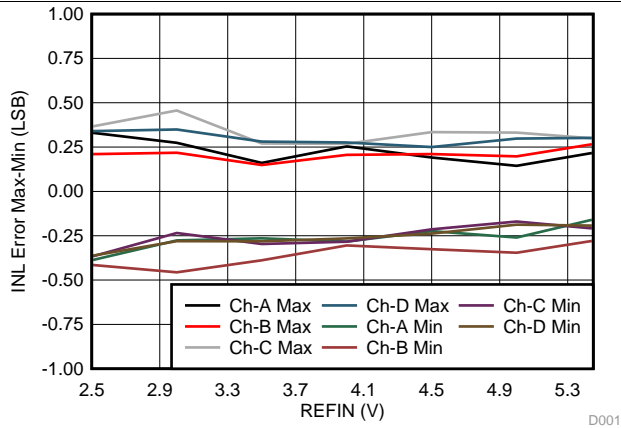


Figure 29. Linearity Error (Max-Min) vs Reference Voltage

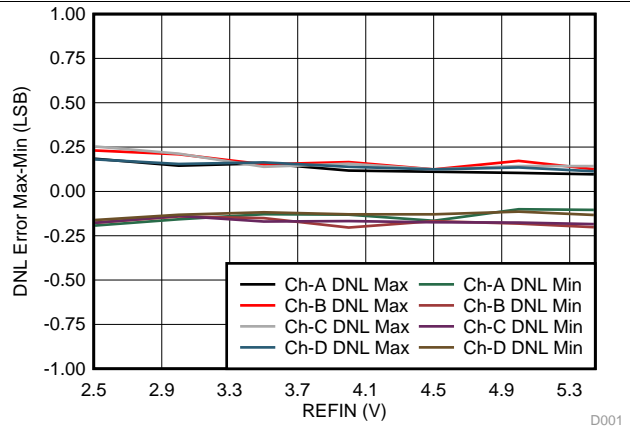


Figure 30. Differential Linearity Error (Max-Min) vs Reference Voltage

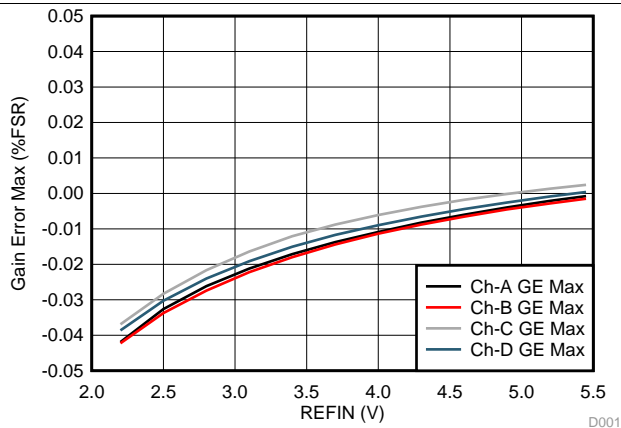


Figure 31. Gain Error (Max) vs Reference Voltage

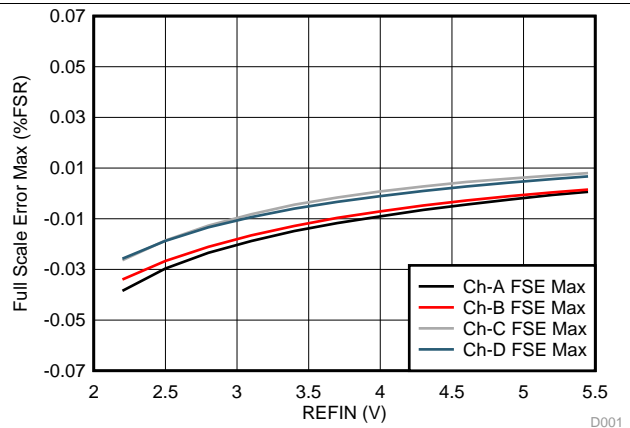


Figure 32. Full Scale Error (Max) vs Reference Voltage

Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, $V_{DD} = 5.5\text{ V}$, $REF_{IN} = 5.45\text{ V}$, DAC outputs unloaded, All channels active, unless otherwise noted.

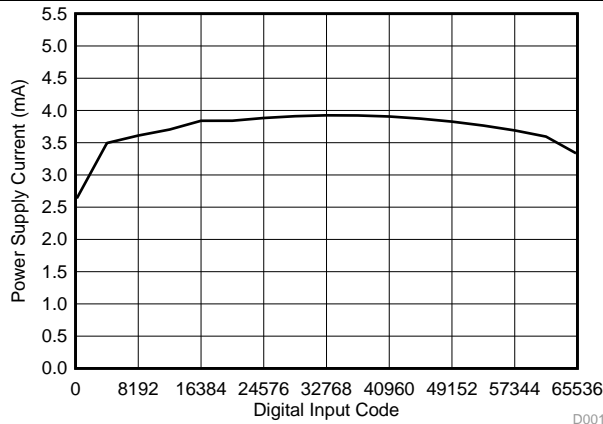
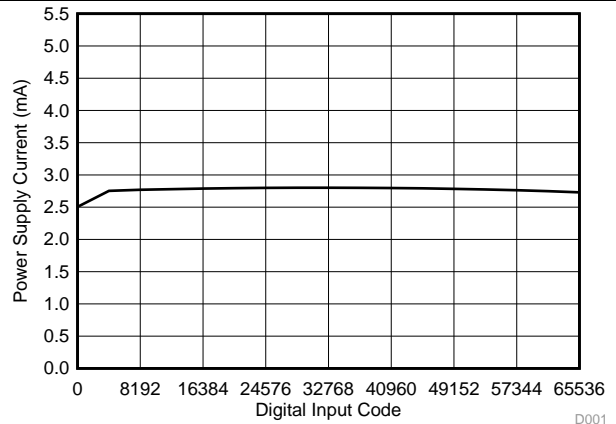
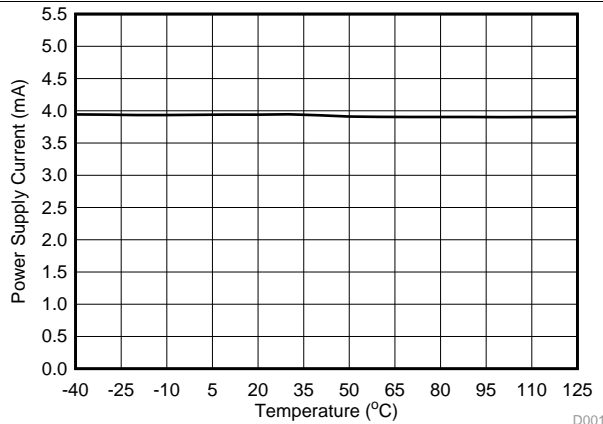


Figure 33. Power Supply Current vs Digital Input Code



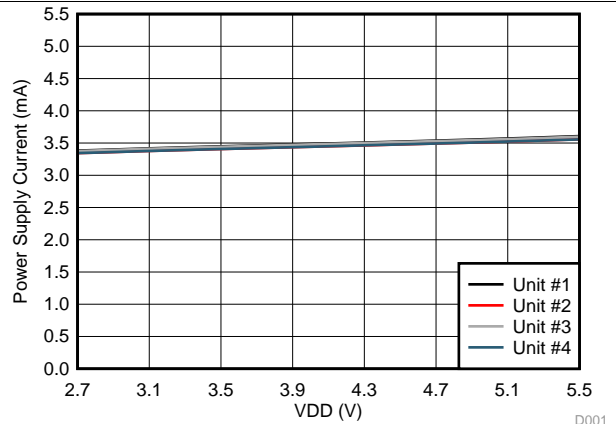
$V_{DD} = 2.7\text{ V}$, $REF_{IN} = 2.5\text{ V}$

Figure 34. Power Supply Current vs Digital Input Code



DAC code = mid-scale code

Figure 35. Power Supply Current vs Temperature



$REF_{IN} = 2.5\text{ V}$, DAC code = mid-scale code

Figure 36. Power Supply Current vs Power Supply Voltage

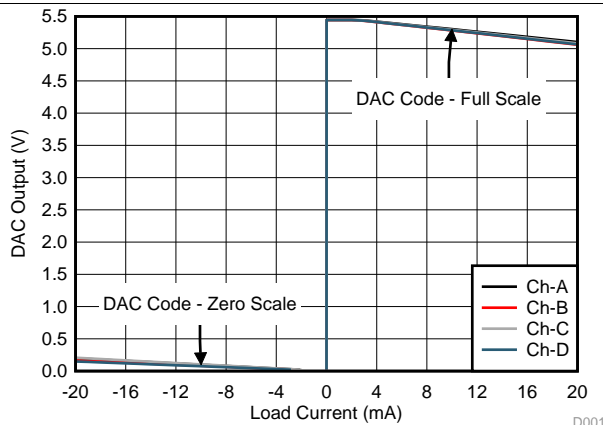
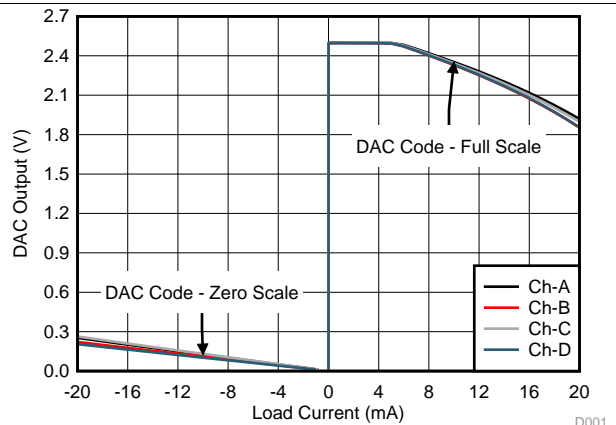


Figure 37. DAC Output Voltage vs Load Current



$V_{DD} = 2.7\text{ V}$, $REF_{IN} = 2.5\text{ V}$

Figure 38. DAC Output Voltage vs Load Current

Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, $V_{DD} = 5.5\text{ V}$, $\text{REFIN} = 5.45\text{ V}$, DAC output load = $5\text{ k}\Omega \parallel 200\text{ pF}$, unless otherwise noted.

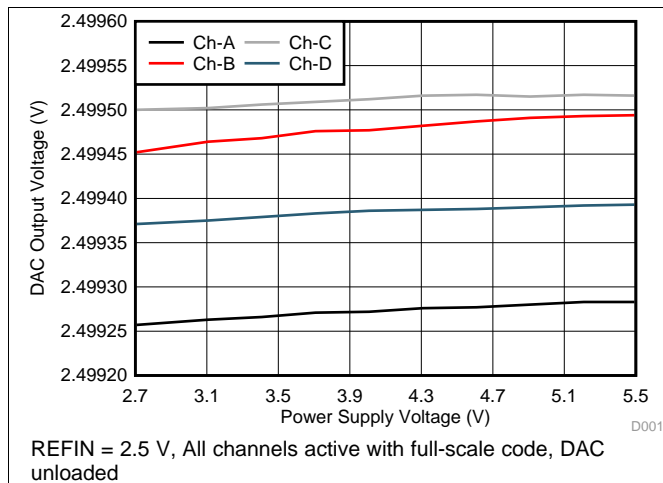


Figure 39. DAC Output Voltage vs Power Supply Voltage

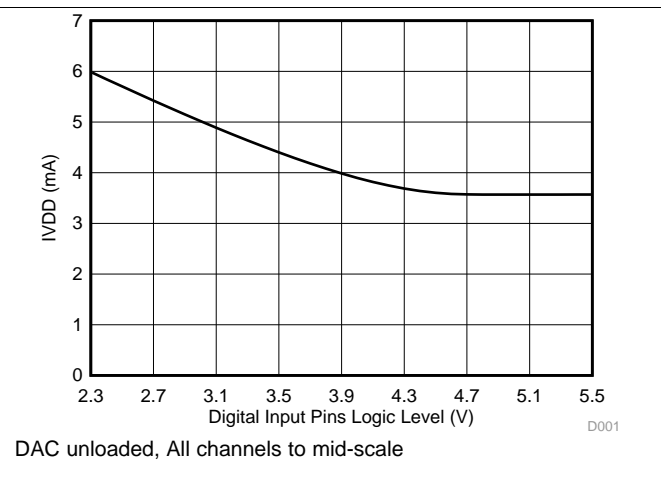


Figure 40. Power Supply Current vs Digital Input Pins Logic Level

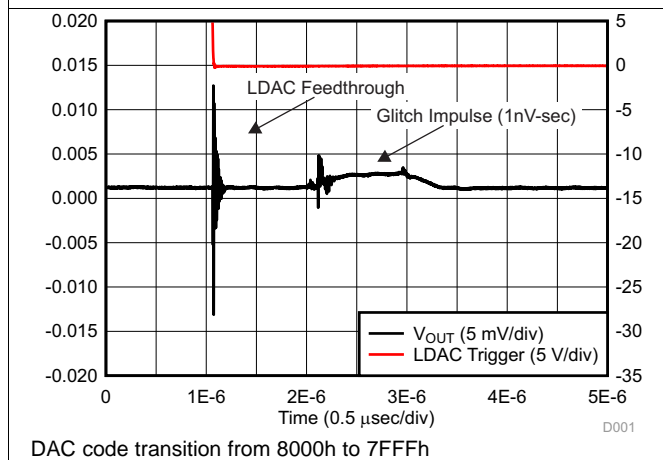


Figure 41. Glitch Impulse, Falling Edge, 1LSB Step

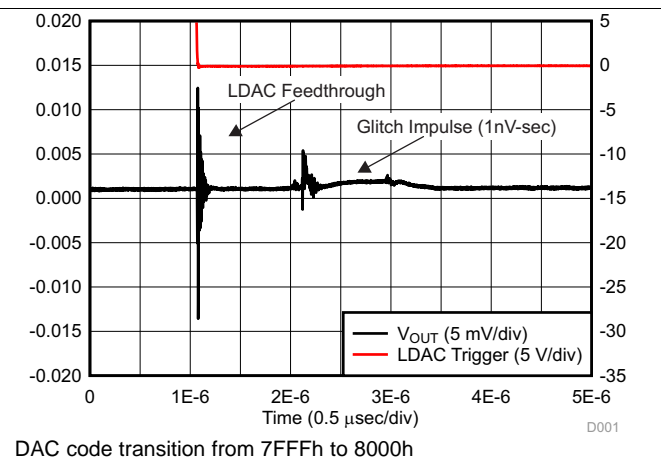


Figure 42. Glitch Impulse, Rising Edge, 1LSB Step

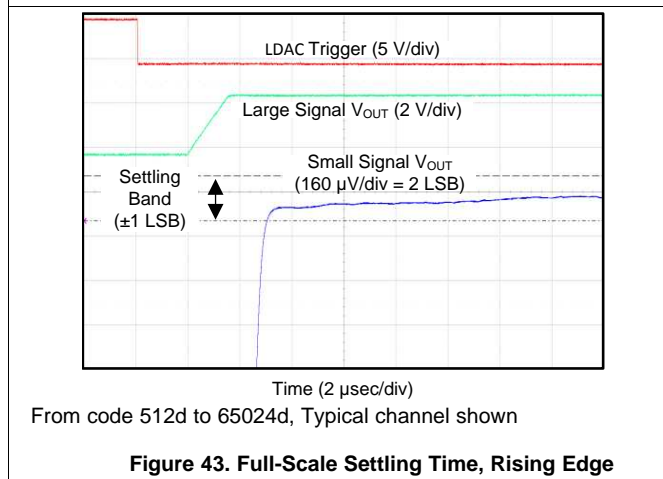


Figure 43. Full-Scale Settling Time, Rising Edge

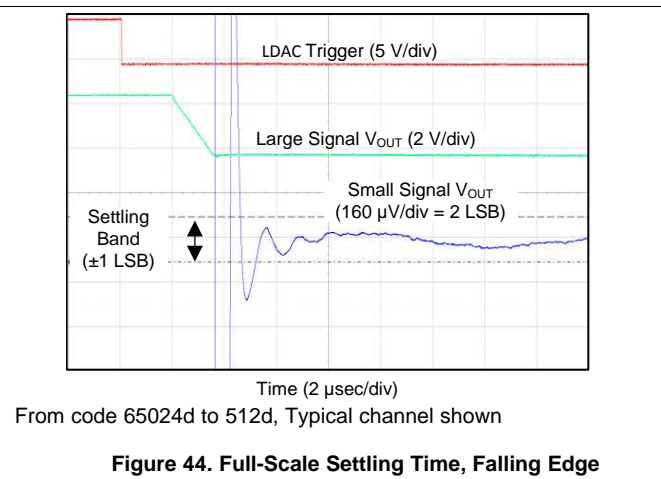
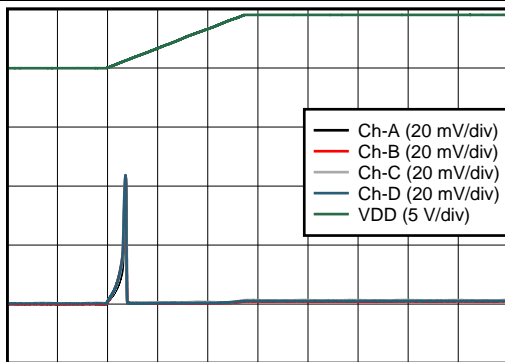


Figure 44. Full-Scale Settling Time, Falling Edge

Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, $V_{DD} = 5.5\text{ V}$, $REFIN = 5.45\text{ V}$, DAC output load = $5\text{ k}\Omega || 200\text{ pF}$, unless otherwise noted.

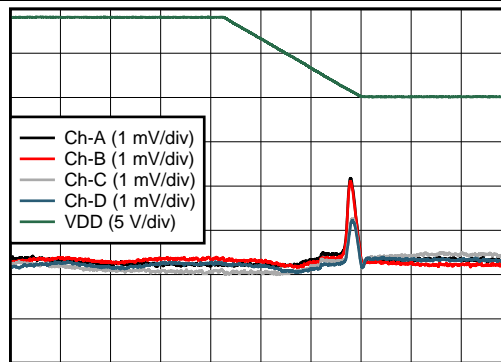


Time (0.2 ms/div)

DAC unloaded

D001

Figure 45. Power-On Glitch, Reset to Zero Scale

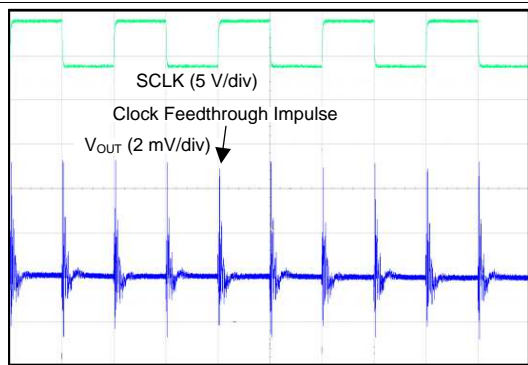


Time (2 ms/div)

DAC in power down mode (1 k Ω -GND)

D001

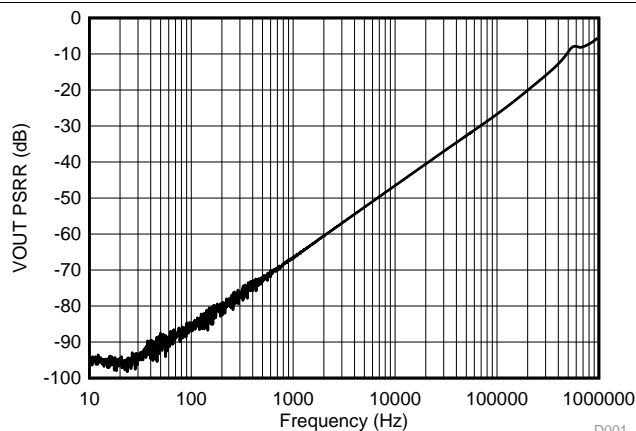
Figure 46. Power-Off Glitch, Reset to Zero Scale



Time (0.5 μs /div)

DAC unloaded, DAC code mid-scale, Typical channel shown

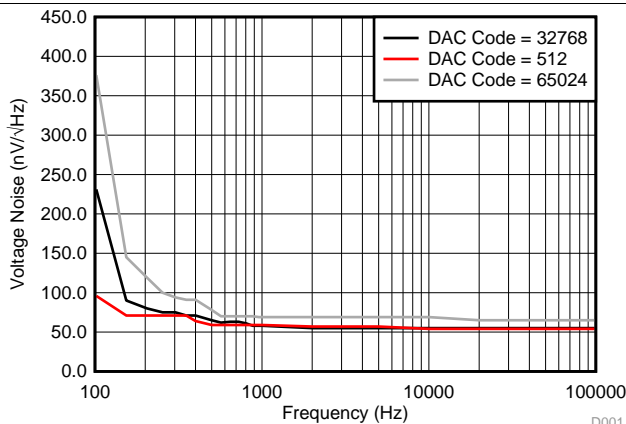
Figure 47. Clock Feedthrough, 1MHz Midscale



$V_{DD} = 5.0 + 1\text{ VPP}$ (Sinusoid), $REFIN = 2.5\text{ V}$, DAC code full-scale, Typical channel shown

D001

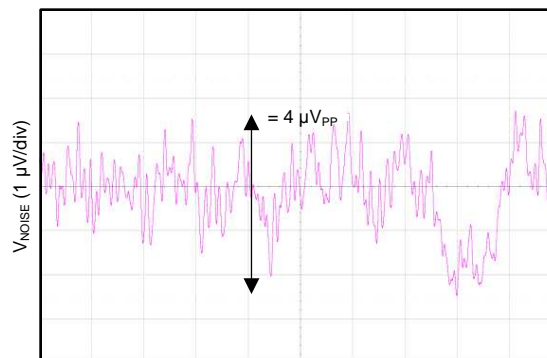
Figure 48. DAC Output AC PSRR vs VDD



DAC unloaded, Typical channel shown

D001

Figure 49. DAC Output Noise Density vs Frequency



DAC unloaded, DAC code mid-scale, Typical channel shown

Figure 50. DAC Output Noise, 0.1 Hz to 10 Hz

8 Detailed Description

8.1 Overview

The DAC80004, DAC70004, and DAC60004 are quad-channel, 16-bit, voltage-output DACs with internal reference buffers and output buffers. Each channel consists of an R-2R ladder configuration with the 4 MSBs segmented, followed by an operational amplifier, as shown in Figure 51. The DACx0004 devices have a constant impedance (30 kΩ typical), buffered reference input. The output of the reference buffers drives the R-2R ladders. With the production trim process these devices have excellent dc accuracy and ac performance.

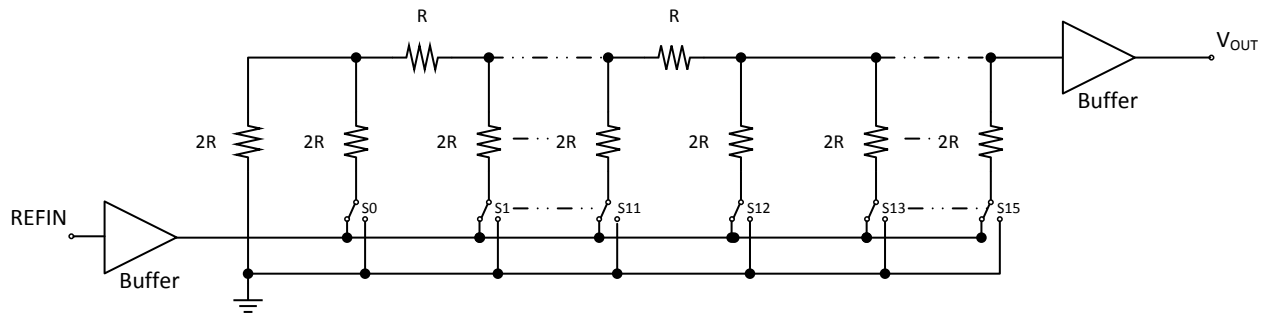


Figure 51. DACx0004 Architecture

The input coding to the DACx0004 is straight binary, so the ideal output voltage is given by Equation 1:

$$V_{OUT} = \left(\frac{D_{IN}}{2^N} \right) \times REF_{IN} \tag{1}$$

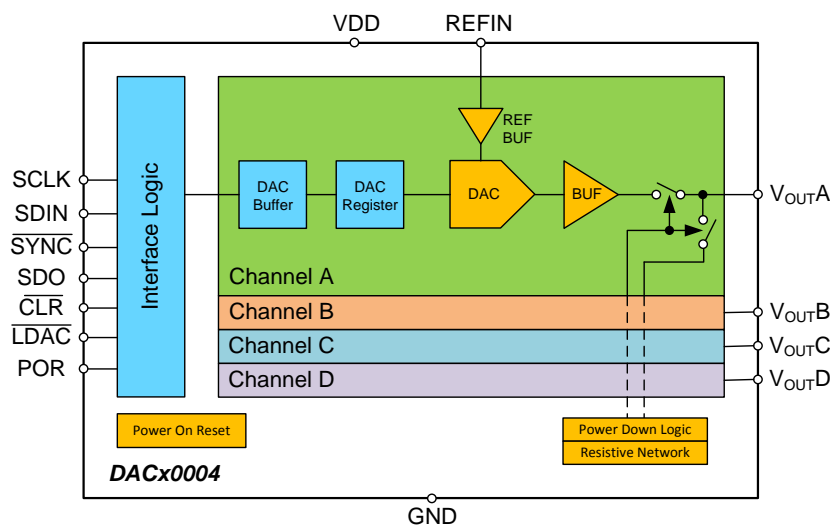
Where:

N = resolution in bits; either 16 (DAC80004), 14 (DAC70004) or 12 (DAC60004)

D_{IN} = decimal equivalent of the binary code that is loaded to the DAC register. D_{IN} ranges from 0 to 2^N – 1

REF_{IN} = DAC reference voltage

8.2 Functional Block Diagram



Copyright © 2016, Texas Instruments Incorporated

8.3 Feature Description

8.3.1 Output Amplifier

The DACx0004 output buffer amplifier is capable of generating near rail-to-rail voltages on its output, giving a maximum output range of 0 V to REFIN. It is capable of driving a load of 5 k Ω in parallel with 2 nF to GND. The typical slew rate of this amplifier while driving no load is 1.5 V/ μ s, with a full-scale settling time of 8 μ s to 1 LSB of the final value as shown in [Figure 43](#) and [Figure 44](#). The current consumption of the amplifier (unloaded) is 1 mA/channel (typical). The DACx0004 output amplifier also implements a short circuit current limiting circuit. The default value of short circuit limit is 40 mA, however this can be reduced to 30 mA using dedicated bits (1 per channel) via SPI command 1010 (see [Table 2](#)).

8.3.2 Reference Buffer

The DACx0004 requires an external reference to operate. The reference input pin has the following input range:

$$2.2 \text{ V to } (V_{DD} - 0.2) \text{ for } 2.7 \text{ V} \leq V_{DD} \leq 4.5 \text{ V}$$

$$2.2 \text{ V to } V_{DD} \text{ for } 4.5 \text{ V} \leq V_{DD} \leq 5.5 \text{ V}$$

The DACx0004 contains a dedicated reference buffer for each DAC channel. The REFIN pin drives the input of these buffers. The integrated reference buffers offers constant impedance of 30 k Ω (typical) at the REFIN pin. This simplifies the external reference drive circuit for the device.

8.3.3 Power-On Reset

The DACx0004 contain a power-on-reset circuit that controls the output voltage during power up. The power-on reset is useful in applications where it is important to know the state of the output of each DAC while the device is in the process of powering up. At power up all DAC registers are filled with power-on reset code (see [Table 1](#)).

8.3.3.1 POR Pin Feature

The DAC power-on reset code for all of the channels depends on the state of the POR pin at power up (see [Pin Configuration and Functions](#)).

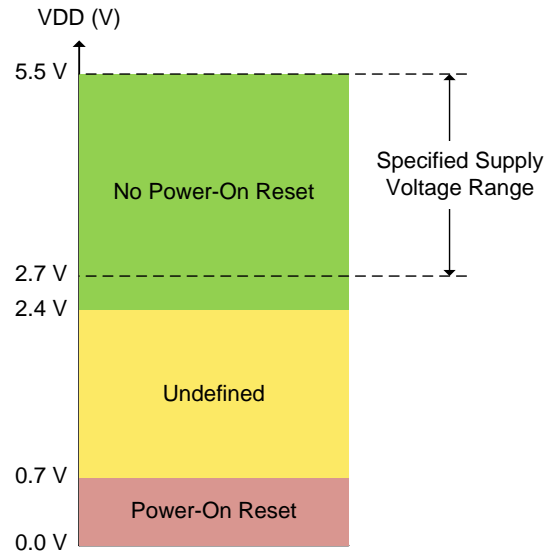
Each DAC channel remains that way until a valid load command is written to it. All device registers are reset at power up as shown in [Table 1](#).

Table 1. DACx0004 Power-On Reset Values

REGISTER NAME	DACx0004 - POWER-ON RESET VALUE
	TSSOP-/VSON-14
DAC latches (per channel)	If POR pin = '0' then Zero Scale else Mid scale
DAC buffers (per channel)	If POR pin= '0' then Zero Scale else Mid scale
Power down (per channel)	00 – Normal mode
Clear mode	00 – Clear to Zero
Ignore LDAC (per channel)	0000 – Do not ignore
Daisy chain	0 – Daisy chain disabled, DAC update at 32nd SCLK falling edge
Short circuit limit (per channel)	0000 – all DACs 40 mA

8.3.3.2 Internal Power-On Reset (IPOR) Levels

When the device powers up, an IPOR circuit sets the device in default mode as shown in [Table 1](#). The IPOR circuit requires specific V_{DD} levels, as indicated in [Figure 52](#), to ensure discharging of internal capacitors and to reset the device on power up. In order to ensure a power-on reset, V_{DD} must be below 0.7 V for at least 1 ms. When V_{DD} drops below 2.4 V but remains above 0.7 V (shown as the undefined region), the device may or may not reset under all specified temperature and power supply conditions. In this case, In this case a power-down reset is recommended. When V_{DD} remains above 2.4 V, a power-on reset does not occur.


Figure 52. Relevant Voltage Levels for IPOR Circuit

8.4 Device Functional Modes

8.4.1 Serial Interface

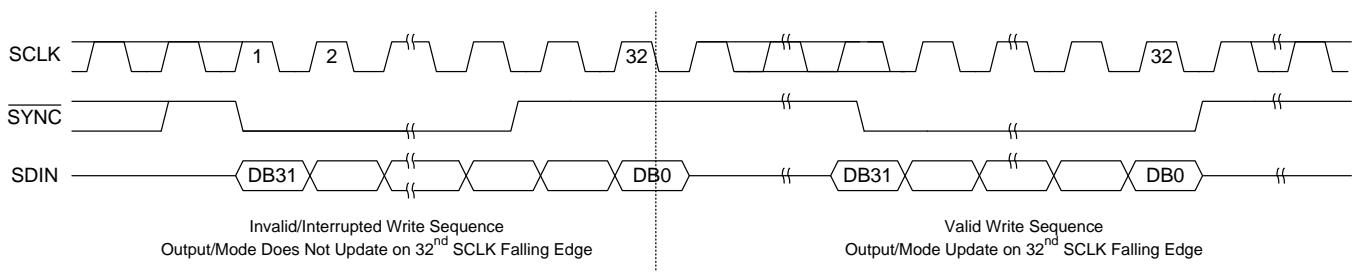
The DACx0004 devices have a 4-wire serial interface: $\overline{\text{SYNC}}$, SCLK, SDIN, and SDO (see [Pin Configuration and Functions](#)). The serial interface (3-wire and 4-wire) is compatible with SPI, QSPI, and Microwire interface standards, as well as most DSPs and it operates up to 50 MHz. See the Write Mode Stand-Alone Timing and Write Mode Daisy-Chain Timing diagrams (see [Figure 1](#) and [Figure 2](#)) for examples of typical write and read sequences. The input shift register is 32 bits wide.

8.4.1.1 Stand-Alone Mode

The serial clock SCLK can be a continuous or a gated clock. The first falling edge of $\overline{\text{SYNC}}$ starts the operation cycle. When $\overline{\text{SYNC}}$ is high, the SCLK and SDIN signals are blocked and the SDO pin (TSSOP-14 and VSON-14 packages) is in a Hi-Z state. The device internal registers are updated from the shift register on the 32nd falling edge of SCLK.

8.4.1.1.1 $\overline{\text{SYNC}}$ Interrupt – Stand-Alone Mode

For stand-alone operation, the $\overline{\text{SYNC}}$ line stays low for at least 32 falling edges of SCLK and the addressed DAC register updates on the 32nd SCLK falling edge. However, if $\overline{\text{SYNC}}$ is brought high before the 32nd SCLK falling edge, it acts as an interrupt to the write sequence; the shift register resets and the write sequence is discarded. Neither an update of the data buffer contents, DAC register contents, nor a change in the operating mode occurs (as shown in [Figure 53](#)).


Figure 53. $\overline{\text{SYNC}}$ Interrupt – Stand Alone Operation

Device Functional Modes (continued)

8.4.1.1.2 Read-Back Mode

The READ command is used to start read-back operation. However, before read-back operation can be initiated, the SDO pin must be enabled by setting the DSDO bit to '1'; this bit is disabled by default. Read-back operation is then started by executing a READ command (R/W bit = '1', see Table 3). Bits C3 to C0 select the register to be read. The remaining data in the command are don't care bits. During the next SPI operation, the data appearing on the SDO output are from the previously addressed register. For a read of a single register, a NOP (No Operation) command (1110) can be used to clock out the data from the selected register on SDO. Multiple registers can be read if multiple READ commands are issued (see Figure 54).

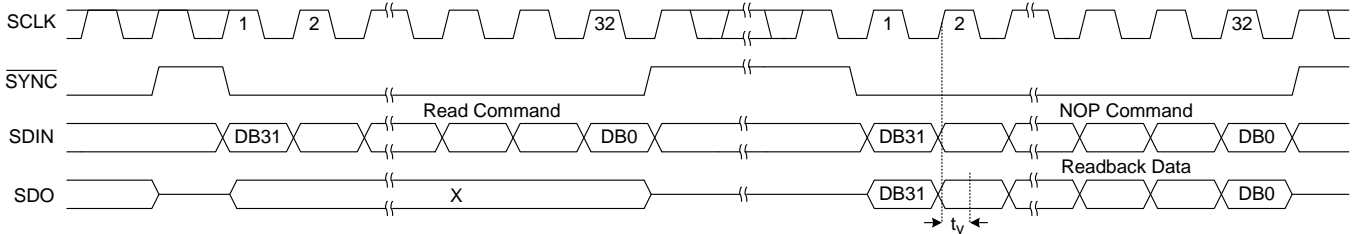


Figure 54. Read-Back Operation

8.4.1.2 Daisy-Chain Mode

For systems that contain more than one device, the SDO pin can be used to daisy-chain multiple devices together (see Figure 55). Daisy-chain operation can be useful in system diagnostics and in reducing the number of serial interface lines. The daisy-chain feature can be enabled by writing a logic '1' to the DSDO bit (see Table 3); the SDO pin is set to HIZ when the DSDO bit is set to 0.

The first falling edge of $\overline{\text{SYNC}}$ starts the operating cycle. SCLK is continuously applied to the SPI shift register when $\overline{\text{SYNC}}$ is low. If more than 32 clock pulses are applied, the data ripples out of the shift register and appear on the SDO line. The data bits are clocked out on the rising edge of SCLK and are valid on the falling edge. By connecting the SDO pin of the first device to the SDI input of the next device in the chain, a multiple-device interface is constructed (see Figure 2). Each device in the system requires 32 clock pulses. Therefore, the total number of clock cycles must equal $32 \times N$, where N is the total number of DACx0004s in the chain. When the serial transfer to all devices is complete, $\overline{\text{SYNC}}$ is taken high. This action latches the data from the SPI shift registers to the device internal registers for each device in the daisy-chain and prevents any further data from being clocked in. The serial clock can be a continuous or a gated clock. Note that a continuous SCLK source can only be used if $\overline{\text{SYNC}}$ is held low for the correct number of clock cycles. For gated clock mode, a burst clock containing the exact number of clock cycles must be used and $\overline{\text{SYNC}}$ must be taken high after the final clock in order to latch the data.

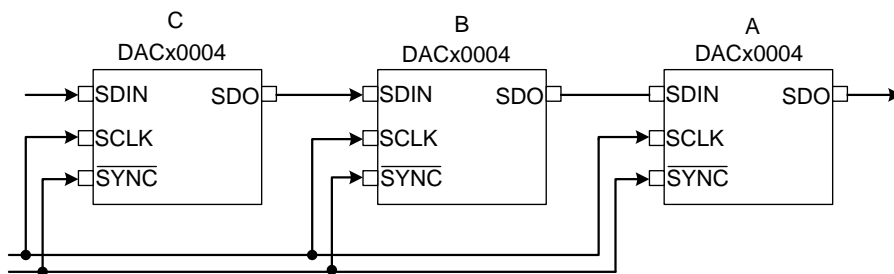


Figure 55. DACx0004 in Daisy Chain Mode

8.4.1.2.1 $\overline{\text{SYNC}}$ Interrupt – Daisy-Chain Mode

For daisy-chain operation, the $\overline{\text{SYNC}}$ line stays low for at least $32 \times N$ SCLK cycles, where N is the number of DACx0004s in the daisy chain. If $\overline{\text{SYNC}}$ is brought high before a multiple 32 SCLKs, it acts as an interrupt to the write sequence; the shift register resets and the write sequence is discarded. Neither an update of the data buffer contents, DAC register contents, nor a change in the operating mode occurs (see Figure 56).

Device Functional Modes (continued)

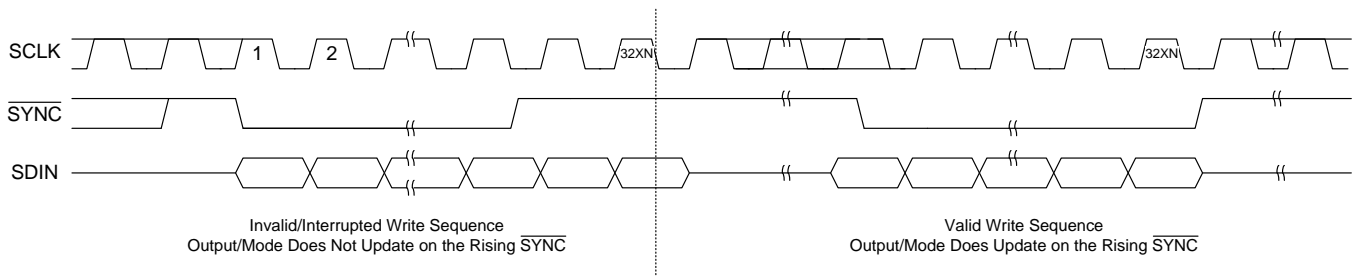


Figure 56. SYNC Interrupt – Daisy-Chain Operation

8.4.2 SPI Shift Register

The SPI shift register is 32 bits wide, as shown in Table 2. The shift register command mapping is shown in Table 3. The DACx0004 accepts DAC code in straight binary format. Note that, the DAC data is left aligned from MSB (D19) to LSB (D4 - 16 bits, D6 - 14 bits, D8 - 12 bits).

Table 2. DACx0004 SPI Shift Register Format

D31	D30	D29	D28	D27-D24	D23-D20	D19-D04	D03-D00
Don't Care			R/W	Command Bits	Channel Address Bits	16/14/12-Bit DAC Data left aligned/Power Down Bits/Device Ready bit	Mode Bits

Table 3. DAC Commands

D31 - D28		D27 - D24				D23 - D20		D19 - D16			D15 - D12			D11 - D08		D07 - D04		D03 - D00				Commands
X	\overline{W}/R	0	0	0	0	Channel Address	DAC Data	DAC Data	DAC Data	DAC Data	DAC Data	DAC Data	DAC Data	DAC Data	DAC Data	DAC Data	DAC Data	X	X	X	X	Write to buffer n
X	\overline{W}	0	0	0	1	Channel Address	X	X	X	X	X	X	X	X	X	X	X	X	X	X	X	Update DAC n
X	\overline{W}	0	0	1	0	Channel Address	DAC Data	DAC Data	DAC Data	DAC Data	DAC Data	DAC Data	DAC Data	DAC Data	DAC Data	DAC Data	DAC Data	X	X	X	X	Write to buffer n and update all DACs (Software LDAC)
X	\overline{W}	0	0	1	1	Channel Address	DAC Data	DAC Data	DAC Data	DAC Data	DAC Data	DAC Data	DAC Data	DAC Data	DAC Data	DAC Data	DAC Data	X	X	X	X	Write to buffer and update DAC n
X	\overline{W}/R	0	1	0	0	X	X	X	X	X	X	X	X	X	X	X	X	Ch-D	Ch-C	Ch-B	Ch-A	Power up/down DAC n
X	\overline{W}/R	0	1	0	1	X	X	X	X	X	X	X	X	X	X	X	X	X	X	CM1	CM0	Clear mode register
X	\overline{W}/R	0	1	1	0	X	X	X	X	X	X	X	X	X	X	X	X	Ch-D	Ch-C	Ch-B	Ch-A	LDAC register
X	\overline{W}	0	1	1	1	X	X	X	X	X	X	X	X	X	X	X	X	X	X	X	X	Software reset
X	\overline{W}/R	1	0	0	0	X	X	X	X	X	X	X	X	X	X	X	X	X	DSD ₀	X	X	Disable SDO register
X	X	1	0	0	1	X	X	X	X	X	X	X	X	X	X	X	X	X	X	X	X	Reserved
X	\overline{W}/R	1	0	1	0	X	X	X	X	X	X	X	X	X	X	X	X	Ch-D	Ch-C	Ch-B	Ch-A	Short circuit limit register
X	\overline{W}	1	0	1	1	X	X	X	X	X	X	X	X	X	X	X	X	X	X	X	X	Software clear
X	X	1	1	0	0	X	X	X	X	X	X	X	X	X	X	X	X	X	X	X	X	Reserved
X	R	1	1	0	1	X	X	X	X	X	X	X	X	X	X	X	X	X	X	DRDY	X	Status register
X	\overline{W}	1	1	1	0	X	X	X	X	X	X	X	X	X	X	X	X	X	X	X	X	No operation (NOP)
X	X	1	1	1	1	X	X	X	X	X	X	X	X	X	X	X	X	X	X	X	X	Reserved

Table 4. Channel Address Bits

CHANNEL ADDRESS BITS				DESCRIPTION
D23	D22	D21	D20	
0	0	0	0	Select channel A
0	0	0	1	Select channel B
0	0	1	0	Select channel C
0	0	1	1	Select channel D
1	1	1	1	Select all channel

8.4.3 DAC Power-Down Modes

The DACx0004 use four modes of operation. These modes are accessed by setting command bits D28 – D24 and power-down register bits D09 and D08. The command bits must be set to 0100 (see Table 3). Once the command bits are set correctly, the four different power-down modes are software programmable by setting bits D09 and D08 in the shift register. Table 5 shows how to control the operating mode with data bits PD1 (D09), PD0 (D08).

Table 5. Power-Down Bits

POWER DOWN BITS		DESCRIPTION
D09	D08	
0	0	Normal operation/power up selected channel(s) (Default)
0	1	Power down selected channel(s) 1 kΩ-GND
1	0	Power down selected channel(s) 100 kΩ-GND
1	1	Power down selected channel(s) Hi-Z

It is possible to write to the DAC register/buffer of the DAC channel that is powered down. When the DAC channel is then powered up, it powers up to this new value.

The advantage of the available power-down modes is that the output impedance of the device is known while it is in power-down mode. As described in Table 5, there are three different power-down options. V_{OUTX} can be connected internally to GND through a 1 kΩ resistor, a 100 kΩ resistor, or open-circuited (Hi-Z). The DAC power-down circuitry is shown in Figure 57.

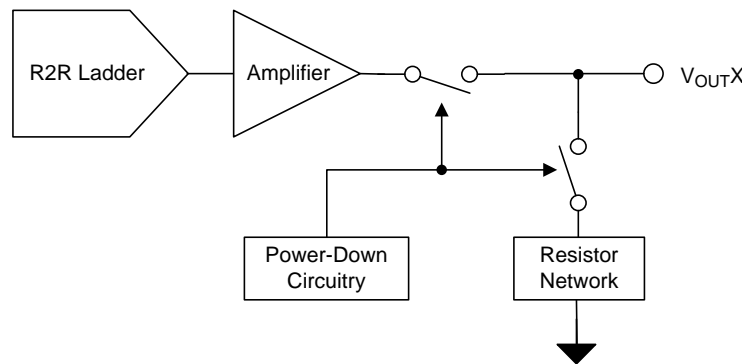


Figure 57. DACx0004 Power Down

8.4.4 $\overline{\text{CLR}}$ Pin Functionality and Software CLEAR Mode

The $\overline{\text{CLR}}$ pin is an asynchronous input pin to the DAC. When activated, this falling edge sensitive pin clears the DAC buffers and the DAC latches to zero, mid, full or user programmed code depending on the clear mode register (see Table 6). The default setting for clear operation is clear to 0 V. The device exits clear mode on the 32nd falling edge of the next write to the device. If the $\overline{\text{CLR}}$ pin receives a falling edge signal during a write sequence in normal operation, the clear mode is activated and changes the input and DAC registers immediately. Additionally, all DAC registers can also be cleared via SPI command 1011. Note that the clear mode bits determine the clear code for all the DACs upon clear operation.

8.4.4.1 DAC Clear Mode Registers

The DACx0004 implement four different clear modes. These modes are accessed by setting command bits D28 – D24 and clear mode register bits D01 and D00. The command bits must be set to 0101 (see Table 3). Based on the value of clear mode register (see Table 6), all of the DAC and the buffers are cleared to zero, mid, or full-scale code, when the $\overline{\text{CLR}}$ pin sees a falling edge or after a software clear command is issued.

The user defined clear scale can be set by writing 16-/14-/12- data to 1001 to bits D28 – D24.

Table 6. Clear Mode Bits

CLEAR MODE BITS		DESCRIPTION
D01	D00	
0	0	All DACs clear to zero scale (default)
0	1	All DACs clear to mid scale
1	0	All DACs clear to full scale

8.4.5 $\overline{\text{LDAC}}$ Pin Functionality

The DACx0004 devices offer both a software and hardware simultaneous update and control function. The DAC double-buffered architecture has been designed so that new data can be entered for each DAC without disturbing the analog outputs. Data updates can be performed either in synchronous or in asynchronous mode.

In asynchronous mode, the $\overline{\text{LDAC}}$ pin is used as an active low signal for simultaneous DAC updates. Multiple single-channel writes can be done in order to set different channel buffers to desired values and then pulse the $\overline{\text{LDAC}}$ pin low to simultaneously update the DAC output registers. Data buffers of all channels must be loaded with desired data before an $\overline{\text{LDAC}}$ low pulse. After a $\overline{\text{LDAC}}$ low pulse, all DACs are simultaneously updated with the last contents of the corresponding data buffers. If the content of a data buffer is not changed, the corresponding DAC output remains unchanged after the $\overline{\text{LDAC}}$ pin is pulsed low.

In synchronous mode, data are updated with the falling edge of the 32nd SCLK cycle, which follows a falling edge of SYNC. For such synchronous updates, the $\overline{\text{LDAC}}$ pin is not required, and it must be connected to GND permanently or asserted and held low before sending commands to the device.

8.4.5.1 Software $\overline{\text{LDAC}}$ Mode Registers

Alternatively, all DAC outputs can be updated simultaneously using the built-in software function of $\overline{\text{LDAC}}$. The $\overline{\text{LDAC}}$ register offers additional flexibility and control by allowing the selection of which DAC channel(s) should be updated simultaneously when the $\overline{\text{LDAC}}$ pin is being brought low. The $\overline{\text{LDAC}}$ register is loaded with a 4-bit word (D03 and D00) using command bits D28 – D24 (see Table 3). The default value for each bit, and therefore for each DAC channel, is zero. If the $\overline{\text{LDAC}}$ register bit is set to 1, it overrides the $\overline{\text{LDAC}}$ pin (the $\overline{\text{LDAC}}$ pin is internally tied low for that particular DAC channel), and this DAC channel updates synchronously after the falling edge of the 32nd SCLK cycle. However, if the $\overline{\text{LDAC}}$ register bit is set to 0, the DAC channel is controlled by the $\overline{\text{LDAC}}$ pin.

See Table 7 for more information.

Table 7. $\overline{\text{LDAC}}$ Register

$\overline{\text{LDAC}}$ REGISTER BITS (D03 – D00)	DAC UPDATE
0	Determined by $\overline{\text{LDAC}}$ pin (Default)
1	DAC channel ignores $\overline{\text{LDAC}}$ pin, DAC updates on 32nd falling edge of SCLK, DAC channels see $\overline{\text{LDAC}}$ as 0

8.4.6 Software Reset Mode

The DACx0004 implements a software reset feature. The software reset function uses command bits D28 – D24 (see Table 3). Table 1 shows the reset values for different registers.

8.4.7 Output Short Circuit Limit Register

The DACx0004 output amplifier has a default short circuit limit of 40 mA. However, this limit can be reduced to 30 mA by using command 1010 on bits D28 – D24 and selecting channel(s) (D03 – D00). Please note that DACx0004 has a dedicated bit per channel, this allows the user to set different short circuit limit for different DAC output channels.

Table 8. Short Circuit Limit Register

SHORT CIRCUIT LIMIT REGISTER BITS (D03 – D00)	DAC SHORT CIRCUIT LIMIT
0	DAC output short circuit limit = 40 mA (Default)
1	DAC output short circuit limit = 30 mA

8.4.8 Status Register

The DACx0004 implements a read-only status register (see [Table 3](#)). This register can be read by using command 1101 on bits D28 – D24, followed by a NOP command.

Logic '1' on bit D04 indicates that the device is ready to be used. This feature is useful to check if the device is ready to accept commands after power up.

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

9.2 Typical Application - Digitally Controlled Asymmetric Bipolar Output

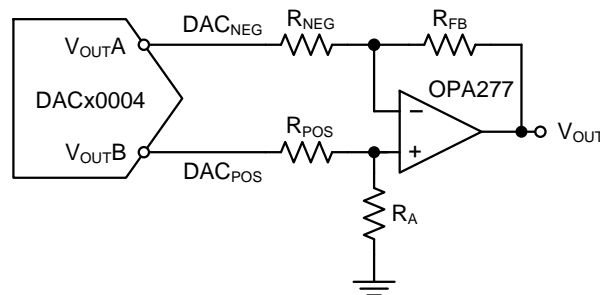


Figure 58. Asymmetric Bipolar Output Block Diagram

9.2.1 Design Requirements

This design requires two channels of the DACx0004 to generate a bipolar output. The design is very flexible and allows for many different configurations. Typically, one channel is used to finely control the output, while the other is used to offset the output. The direction of the offset depends on which channel is used as an offset. DAC_{POS} provides a positive offset and DAC_{NEG} has a negative offset.

9.2.2 Detailed Design Procedure

The output of each DAC can be modified via the digital interface and the gain of each output can be modified independently by changing the external resistors. In order for the gain of each offset to be independent, [Equation 2](#) must be true.

$$R_A = \left(\frac{1}{R_{FB}} + \frac{1}{R_{NEG}} - \frac{1}{R_{POS}} \right)^{-1} \quad (2)$$

The output voltage range, V_{OUT} , is adjusted according to [Equation 3](#). Keep in mind that [Equation 3](#) is only true when [Equation 2](#) is true.

$$V_{OUT} = DAC_{POS} \times \frac{R_{FB}}{R_{POS}} - DAC_{NEG} \times \frac{R_{FB}}{R_{NEG}} \quad (3)$$

Each DAC outputs a voltage from 0 to REFIN. As an example, if DAC_{POS} gain is 1, DAC_{NEG} gain is 2 and $R_{FB} = 2 \text{ k}\Omega$, then $R_{POS} = 2 \text{ k}\Omega$, $R_{NEG} = 1 \text{ k}\Omega$ and $R_A = 1 \text{ k}\Omega$. With the correct digital implementation it gives the output an effective output range of $\pm 15 \text{ V}$, with discrete 16-bit steps.

Typical Application - Digitally Controlled Asymmetric Bipolar Output (continued)

9.2.3 Application Curve

Figure 59 displays two different modes of operation. Mode 1 gains the output of DAC_{Neg} by a factor of 2 and maintains DAC_{Pos} at unity gain. Mode 2 reverses the gains of each stage to invert the system. These are just two examples of the types of outputs that can be achieved using this configuration.

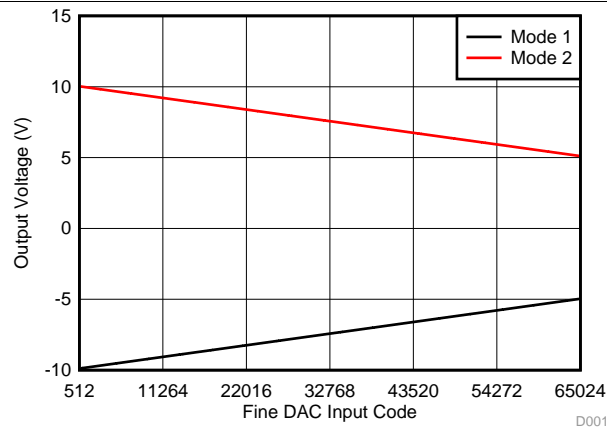


Figure 59. Output Voltage vs Fine DAC Input Code

10 Power Supply Recommendations

The DACx0004 can operate within the specified supply voltage range of 2.7 V to 5.5 V. The power applied to VDD should be well-regulated and have low-noise. Switching power supplies and DC-DC converters often have high frequency glitches or spikes riding on the output voltage. In addition, digital components can create similar high frequency spikes. This noise can easily couple into the DAC output voltage through various paths between the power connections and analog output. A 1 μ F to 10 μ F capacitor and 0.1 μ F bypass capacitor is recommended in order to further minimize noise from the power supply. The current consumption on the VDD pin, the short-circuit current limit, and the load current for the device are listed in the [Electrical Characteristics](#). The power supply must meet the aforementioned current requirements.

11 Layout

11.1 Layout Guidelines

A precision analog component requires careful layout, adequate bypassing, and clean, well-regulated power supplies. As a general rule it is important to keep digital traces as far away from analog traces when possible.

The DACx0004 is often used in close proximity with digital logic, microcontrollers, microprocessors, and digital signal processors. The more digital logic present in the design and the higher the switching speed, the more difficult it is to keep digital noise from appearing at the output.

Due to the single ground pin of the DACx0004, all return currents, including digital and analog return currents for the DAC, must flow through a single point. Ideally, GND must be connected directly to an analog ground plane. This plane must be separate from the ground connection for the digital components until they were connected at the power-entry point of the system.

As with the GND connection, VDD should be connected to a 5 V power-supply plane or trace that is separate from the connection for digital logic until they are connected at the power-entry point. It is recommended to have an additional 1 μF to 10 μF capacitor and 0.1 μF bypass capacitor. In some situations, additional bypassing may be required, such as a 100 μF electrolytic capacitor or even a Pi filter made up of inductors and capacitors—all designed to essentially low-pass filter the 5 V supply, removing the high-frequency noise. In general it is always a good idea to maintain the digital signals away from analog signals.

11.2 Layout Example

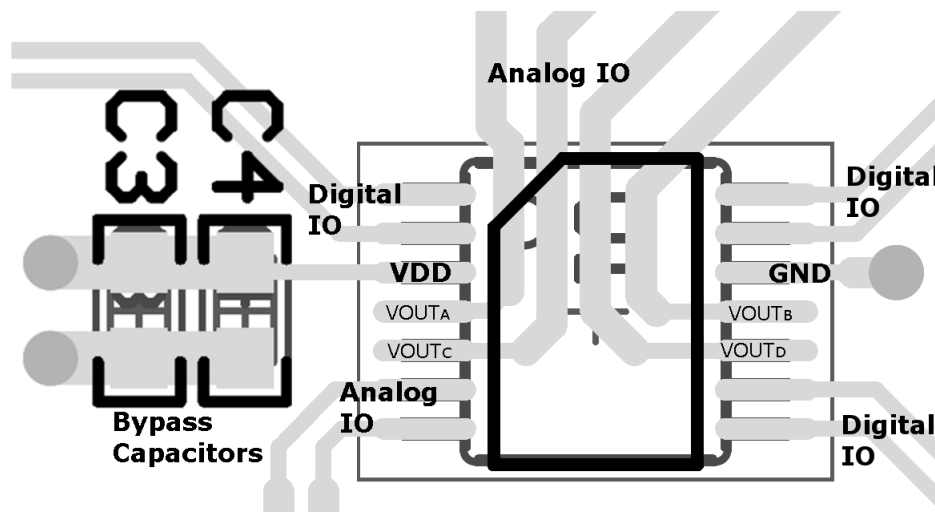


Figure 60. Layout Diagram

12 器件和文档支持

12.1 相关链接

下面的表格列出了快速访问链接。范围包括技术文档、支持和社区资源、工具和软件，以及样片或购买的快速访问。

表 9. 相关链接

器件	产品文件夹	样片与购买	技术文档	工具与软件	支持与社区
DAC60004	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
DAC70004	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
DAC80004	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处

12.2 社区资源

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.3 商标

E2E is a trademark of Texas Instruments.

SPI, QSPI are trademarks of Motorola.

All other trademarks are the property of their respective owners.

12.4 静电放电警告



这些装置包含有限的内置 ESD 保护。存储或装卸时，应将导线一起截短或将装置放置于导电泡棉中，以防止 MOS 门极遭受静电损伤。

12.5 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 机械、封装和可订购信息

以下页中包括机械、封装和可订购信息。这些信息是针对指定器件可提供的最新数据。这些数据会在无通知且不对本文档进行修订的情况下发生改变。欲获得该数据表的浏览器版本，请查阅左侧的导航栏。

重要声明

德州仪器(TI)及其下属子公司有权根据 JESD46 最新标准,对所提供的产品和服务进行更正、修改、增强、改进或其它更改,并有权根据 JESD48 最新标准中止提供任何产品和服务。客户在下订单前应获取最新的相关信息,并验证这些信息是否完整且是最新的。所有产品的销售都遵循在订单确认时所提供的TI 销售条款与条件。

TI 保证其所销售的组件的性能符合产品销售时 TI 半导体产品销售条件与条款的适用规范。仅在 TI 保证的范围内,且 TI 认为有必要时才会使用测试或其它质量控制技术。除非适用法律做出了硬性规定,否则没有必要对每种组件的所有参数进行测试。

TI 对应用帮助或客户产品设计不承担任何义务。客户应对其使用 TI 组件的产品和应用自行负责。为尽量减小与客户产品和应用相关的风险,客户应提供充分的设计与操作安全措施。

TI 不对任何 TI 专利权、版权、屏蔽作品权或其它与使用了 TI 组件或服务的组合设备、机器或流程相关的 TI 知识产权中授予的直接或隐含权限作出任何保证或解释。TI 所发布的与第三方产品或服务有关的信息,不能构成从 TI 获得使用这些产品或服务的许可、授权、或认可。使用此类信息可能需要获得第三方的专利权或其它知识产权方面的许可,或是 TI 的专利权或其它知识产权方面的许可。

对于 TI 的产品手册或数据表中 TI 信息的重要部分,仅在没有对内容进行任何篡改且带有相关授权、条件、限制和声明的情况下才允许进行复制。TI 对此类篡改过的文件不承担任何责任或义务。复制第三方的信息可能需要服从额外的限制条件。

在转售 TI 组件或服务时,如果对该组件或服务参数的陈述与 TI 标明的参数相比存在差异或虚假成分,则会失去相关 TI 组件或服务的所有明示或暗示授权,且这是不正当的、欺诈性商业行为。TI 对任何此类虚假陈述均不承担任何责任或义务。

客户认可并同意,尽管任何应用相关信息或支持仍可能由 TI 提供,但他们将独立负责满足与其产品及其在应用中使用的 TI 产品相关的所有法律、法规和安全相关要求。客户声明并同意,他们具备制定与实施安全措施所需的全部专业技术和知识,可预见故障的危险后果、监测故障及其后果、降低有可能造成人身伤害的故障的发生机率并采取适当的补救措施。客户将全额赔偿因在此类安全关键应用中使用任何 TI 组件而对 TI 及其代理造成的任何损失。

在某些场合中,为了推进安全相关应用有可能对 TI 组件进行特别的促销。TI 的目标是利用此类组件帮助客户设计和创立其特有的可满足适用的功能安全性标准和要求的终端产品解决方案。尽管如此,此类组件仍然服从这些条款。

TI 组件未获得用于 FDA Class III (或类似的生命攸关医疗设备)的授权许可,除非各方授权官员已经达成了专门管控此类使用的特别协议。

只有那些 TI 特别注明属于军用等级或“增强型塑料”的 TI 组件才是设计或专门用于军事/航空应用或环境的。购买者认可并同意,对并非指定面向军事或航空航天用途的 TI 组件进行军事或航空航天方面的应用,其风险由客户单独承担,并且由客户独立负责满足与此类使用相关的所有法律和法规要求。

TI 已明确指定符合 ISO/TS16949 要求的产品,这些产品主要用于汽车。在任何情况下,因使用非指定产品而无法达到 ISO/TS16949 要求, TI 不承担任何责任。

	产品		应用
数字音频	www.ti.com.cn/audio	通信与电信	www.ti.com.cn/telecom
放大器和线性器件	www.ti.com.cn/amplifiers	计算机及周边	www.ti.com.cn/computer
数据转换器	www.ti.com.cn/dataconverters	消费电子	www.ti.com.cn/consumer-apps
DLP® 产品	www.dlp.com	能源	www.ti.com.cn/energy
DSP - 数字信号处理器	www.ti.com.cn/dsp	工业应用	www.ti.com.cn/industrial
时钟和计时器	www.ti.com.cn/clockandtimers	医疗电子	www.ti.com.cn/medical
接口	www.ti.com.cn/interface	安防应用	www.ti.com.cn/security
逻辑	www.ti.com.cn/logic	汽车电子	www.ti.com.cn/automotive
电源管理	www.ti.com.cn/power	视频和影像	www.ti.com.cn/video
微控制器 (MCU)	www.ti.com.cn/microcontrollers		
RFID 系统	www.ti.com.cn/rfidsys		
OMAP应用处理器	www.ti.com/omap		
无线连通性	www.ti.com.cn/wirelessconnectivity	德州仪器在线技术支持社区	www.deyisupport.com

邮寄地址: 上海市浦东新区世纪大道1568号, 中建大厦32楼邮政编码: 200122
Copyright © 2016, 德州仪器半导体技术(上海)有限公司

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
DAC60004IDMDR	ACTIVE	VSON	DMD	14	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	DA60004	Samples
DAC60004IDMDT	ACTIVE	VSON	DMD	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	DA60004	Samples
DAC60004IPW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	DA60004	Samples
DAC60004IPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	DA60004	Samples
DAC70004IDMDR	ACTIVE	VSON	DMD	14	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	DA70004	Samples
DAC70004IDMDT	ACTIVE	VSON	DMD	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	DA70004	Samples
DAC70004IPW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	DA70004	Samples
DAC70004IPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	DA70004	Samples
DAC80004IDMDR	ACTIVE	VSON	DMD	14	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	DA80004	Samples
DAC80004IDMDT	ACTIVE	VSON	DMD	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	DA80004	Samples
DAC80004IPW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	DA80004	Samples
DAC80004IPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	DA80004	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

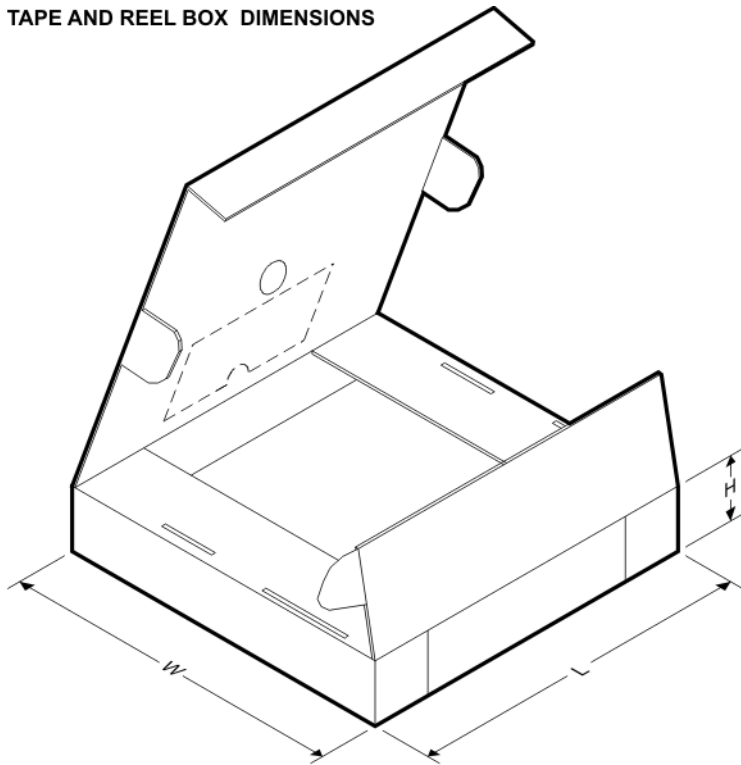
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DAC60004IDMDT	VSON	DMD	14	250	180.0	12.4	3.3	4.3	1.1	8.0	12.0	Q1
DAC60004IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
DAC70004IDMDT	VSON	DMD	14	250	180.0	12.4	3.3	4.3	1.1	8.0	12.0	Q1
DAC70004IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
DAC80004IDMDT	VSON	DMD	14	250	180.0	12.4	3.3	4.3	1.1	8.0	12.0	Q1
DAC80004IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal



Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DAC60004IDMDT	VSON	DMD	14	250	195.0	200.0	45.0
DAC60004IPWR	TSSOP	PW	14	2000	367.0	367.0	35.0
DAC70004IDMDT	VSON	DMD	14	250	195.0	200.0	45.0
DAC70004IPWR	TSSOP	PW	14	2000	367.0	367.0	35.0
DAC80004IDMDT	VSON	DMD	14	250	195.0	200.0	45.0
DAC80004IPWR	TSSOP	PW	14	2000	367.0	367.0	35.0

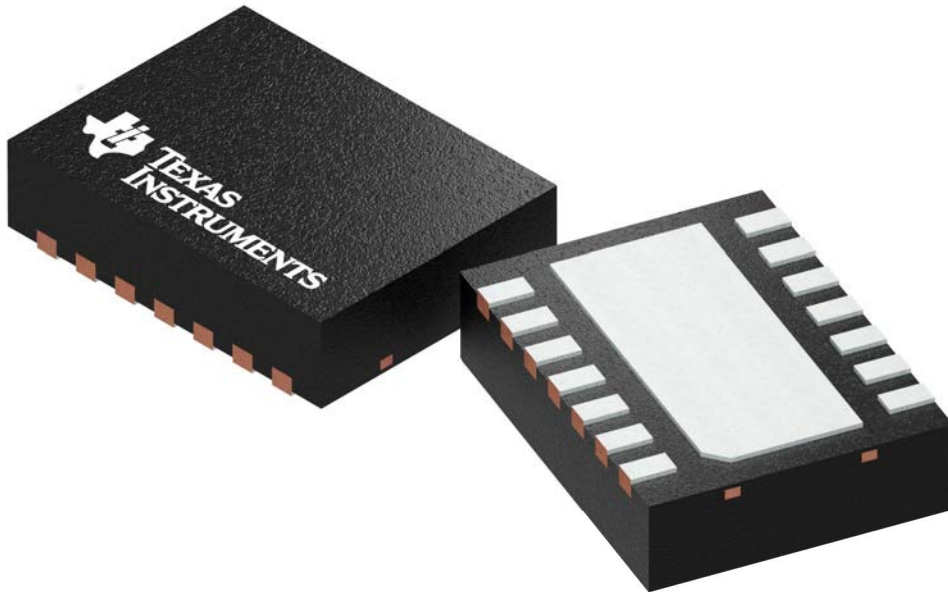
PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE

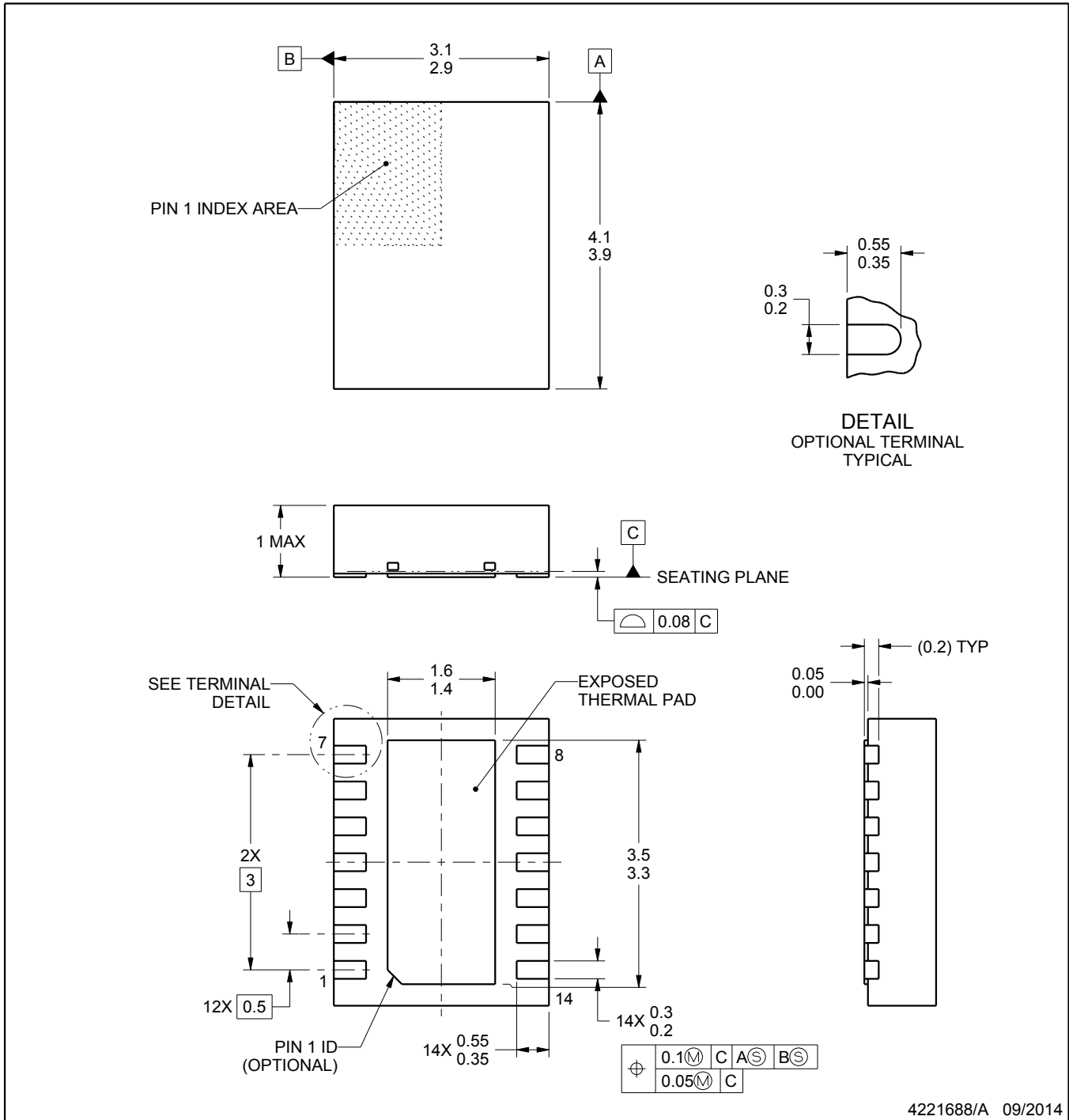
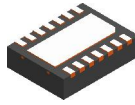


4040064-3/G 02/11

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 -  C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
 -  D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
 - E. Falls within JEDEC MO-153



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



NOTES:

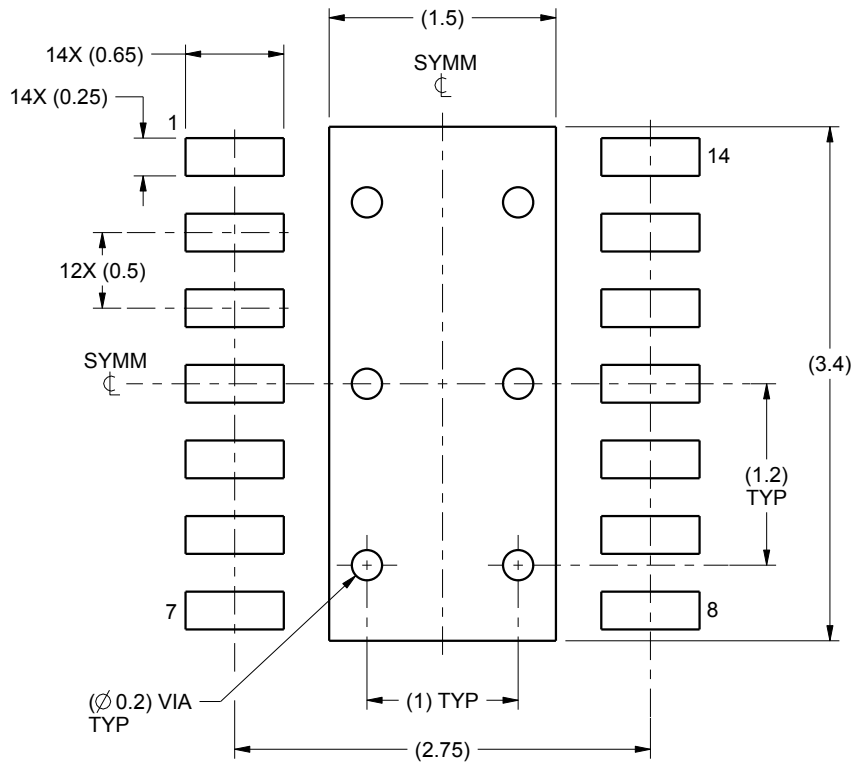
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

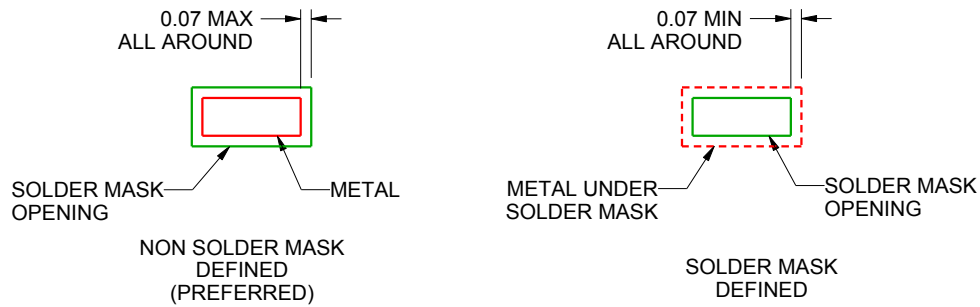
DMD0014A

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
SCALE:20X



SOLDER MASK DETAILS

4221688/A 09/2014

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sl原因271).
5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

重要声明

德州仪器(TI) 及其下属子公司有权根据 JESD46 最新标准, 对所提供的产品和服务进行更正、修改、增强、改进或其它更改, 并有权根据 JESD48 最新标准中止提供任何产品和服务。客户在下订单前应获取最新的相关信息, 并验证这些信息是否完整且是最新的。所有产品的销售都遵循在订单确认时所提供的TI 销售条款与条件。

TI 保证其所销售的组件的性能符合产品销售时 TI 半导体产品销售条件与条款的适用规范。仅在 TI 保证的范围内, 且 TI 认为有必要时才会使用测试或其它质量控制技术。除非适用法律做出了硬性规定, 否则没有必要对每种组件的所有参数进行测试。

TI 对应用帮助或客户产品设计不承担任何义务。客户应对其使用 TI 组件的产品和应用自行负责。为尽量减小与客户产品和应用相关的风险, 客户应提供充分的设计与操作安全措施。

TI 不对任何 TI 专利权、版权、屏蔽作品权或其它与使用了 TI 组件或服务的组合设备、机器或流程相关的 TI 知识产权中授予的直接或间接侵权作出任何保证或解释。TI 所发布的与第三方产品或服务有关的信息, 不能构成从 TI 获得使用这些产品或服务的许可、授权、或认可。使用此类信息可能需要获得第三方的专利权或其它知识产权方面的许可, 或是 TI 的专利权或其它知识产权方面的许可。

对于 TI 的产品手册或数据表中 TI 信息的重要部分, 仅在没有对内容进行任何篡改且带有相关授权、条件、限制和声明的情况下才允许进行复制。TI 对此类篡改过的文件不承担任何责任或义务。复制第三方的信息可能需要服从额外的限制条件。

在转售 TI 组件或服务时, 如果对该组件或服务参数的陈述与 TI 标明的参数相比存在差异或虚假成分, 则会失去相关 TI 组件或服务的所有明示或暗示授权, 且这是不正当的、欺诈性商业行为。TI 对任何此类虚假陈述均不承担任何责任或义务。

客户认可并同意, 尽管任何应用相关信息或支持仍可能由 TI 提供, 但他们将独自负责满足与其产品及其应用中使用 TI 产品相关的所有法律、法规和安全相关要求。客户声明并同意, 他们具备制定与实施安全措施所需的全部专业技术和知识, 可预见故障的危险后果、监测故障及其后果、降低有可能造成人身伤害的故障的发生机率并采取适当的补救措施。客户将全额赔偿因在此类安全关键应用中使用任何 TI 组件而对 TI 及其代理造成的任何损失。

在某些场合中, 为了推进安全相关应用有可能对 TI 组件进行特别的促销。TI 的目标是利用此类组件帮助客户设计和创立其特有的可满足适用的功能安全性标准和要求的终端产品解决方案。尽管如此, 此类组件仍然服从这些条款。

TI 组件未获得用于 FDA Class III (或类似的生命攸关医疗设备) 的授权许可, 除非各方授权官员已经达成了专门管控此类使用的特别协议。

只有那些 TI 特别注明属于军用等级或“增强型塑料”的 TI 组件才是设计或专门用于军事/航空应用或环境的。购买者认可并同意, 对并非指定面向军事或航空航天用途的 TI 组件进行军事或航空航天方面的应用, 其风险由客户单独承担, 并且由客户独自负责满足与此类使用相关的所有法律和法规要求。

TI 已明确指定符合 ISO/TS16949 要求的产品, 这些产品主要用于汽车。在任何情况下, 因使用非指定产品而无法达到 ISO/TS16949 要求, TI 不承担任何责任。

	产品		应用
数字音频	www.ti.com.cn/audio	通信与电信	www.ti.com.cn/telecom
放大器和线性器件	www.ti.com.cn/amplifiers	计算机及周边	www.ti.com.cn/computer
数据转换器	www.ti.com.cn/dataconverters	消费电子	www.ti.com.cn/consumer-apps
DLP® 产品	www.dlp.com	能源	www.ti.com.cn/energy
DSP - 数字信号处理器	www.ti.com.cn/dsp	工业应用	www.ti.com.cn/industrial
时钟和计时器	www.ti.com.cn/clockandtimers	医疗电子	www.ti.com.cn/medical
接口	www.ti.com.cn/interface	安防应用	www.ti.com.cn/security
逻辑	www.ti.com.cn/logic	汽车电子	www.ti.com.cn/automotive
电源管理	www.ti.com.cn/power	视频和影像	www.ti.com.cn/video
微控制器 (MCU)	www.ti.com.cn/microcontrollers		
RFID 系统	www.ti.com.cn/rfidsys		
OMAP应用处理器	www.ti.com.cn/omap		
无线连通性	www.ti.com.cn/wirelessconnectivity	德州仪器在线技术支持社区	www.deyisupport.com

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2016, Texas Instruments Incorporated